## INTEGRATED CIRCUITS

# DATA SHEET

## 80C51/87C51/80C52/87C52

80C51 8-bit microcontroller family 4 K/8 K OTP/ROM low voltage (2.7 V-5.5 V), low power, high speed (33 MHz), 128/256 B RAM

Product specification Replaces datasheet 80C51/87C51/80C31 of 2000 Jan 20





Philips Semiconductors Product specification

## 80C51 8-bit microcontroller family 4 K/8 K OTP/ROM low voltage (2.7 V-5.5 V), low power, high speed (33 MHz), 128/256 B RAM

## 80C51/87C51/80C52/87C52

#### DESCRIPTION

The Philips 80C51/87C51/80C52/87C52 is a high-performance static 80C51 design fabricated with Philips high-density CMOS technology with operation from 2.7 V to 5.5 V.

The 8xC51 and 8xC52 contain a 128  $\times$  8 RAM and 256  $\times$  8 RAM respectively, 32 I/O lines, three 16-bit counter/timers, a six-source, four-priority level nested interrupt structure, a serial I/O port for either multi-processor communications, I/O expansion or full duplex UART, and on-chip oscillator and clock circuits.

In addition, the device is a low power static design which offers a wide range of operating frequencies down to zero. Two software selectable modes of power reduction—idle mode and power-down mode are available. The idle mode freezes the CPU while allowing the RAM, timers, serial port, and interrupt system to continue functioning. The power-down mode saves the RAM contents but freezes the oscillator, causing all other chip functions to be inoperative. Since the design is static, the clock can be stopped without loss of user data and then the execution resumed from the point the clock was stopped.

#### **SELECTION TABLE**

For applications requiring more ROM and RAM, see the 8XC54/58 and 8XC51RA+/RB+/RC+/80C51RA+ data sheet.

Note: 80C31/80C32 is specified in separate data sheet.

ROM/EPROM Memory Size (X by 8)	RAM Size (X by 8)	Programmable Timer Counter (PCA)	Hardware Watch Dog Timer				
80C31*/80C51/87C51							
0K/4K	128	No					
80C32*/80C52/8	7C52						
0K/8K/16K/32K	256	No	No				
80C51RA+/8XC5	1RA+/RB+/RC	<b>.</b>					
0K/8K/16K/32K	512	Yes	Yes				
8XC51RD+							
64K	1024	Yes	Yes				

#### **FEATURES**

- 8051 Central Processing Unit
  - 4k × 8 ROM (80C51)
  - 8k × 8 ROM (80C52)
  - 128 × 8 RAM (80C51)
  - 256 × 8 RAM (80C52)
  - Three 16-bit counter/timers
  - Boolean processor
- Full static operation
- Low voltage (2.7 V to 5.5 V@ 16 MHz) operation
- Memory addressing capability
  - 64k ROM and 64k RAM
- Power control modes:
- Clock can be stopped and resumed
- Idle mode
- Power-down mode
- CMOS and TTL compatible
- TWO speed ranges at V<sub>CC</sub> = 5 V
  - 0 to 16 MHz
  - 0 to 33 MHz
- Three package styles
- Extended temperature ranges
- Dual Data Pointers
- Security bits:
  - ROM (2 bits)
  - OTP/EPROM (3 bits)
- Encryption array 64 bytes
- 4 level priority interrupt
- 6 interrupt sources
- Four 8-bit I/O ports
- Full-duplex enhanced UART
  - Framing error detection
  - Automatic address recognition
- Programmable clock out
- Asynchronous port reset
- Low EMI (inhibit ALE and slew rate controlled outputs)
- Wake-up from Power Down by an external interrupt

## 80C51/87C51/80C52/87C52

#### 80C51/87C51 ORDERING INFORMATION

	MEMORY SIZE 4K×8	TEMPERATURE RANGE °C AND PACKAGE	VOLTAGE RANGE	FREQ. (MHz)	DWG.#
ROM	P80C51SBPN	0 to 170 Pleatic Duel la line Package	2.7 V to 5.5 V	0 to 40	SOT129-1
OTP	P87C51SBPN	0 to +70, Plastic Dual In-line Package	2.7 V to 5.5 V	0 to 16	501129-1
ROM	P80C51SBAA	O to 170 Plantial and of Chia Courier	0.7.1/40.5.5.1/	0 4= 40	COT407.0
ОТР	P87C51SBAA	0 to +70, Plastic Leaded Chip Carrier	2.7 V to 5.5 V	0 to 16	SOT187-2
ROM	P80C51SBBB	O to 170 Pleatic Out Flat Paul	0.7.1/45.5.5.1/	0 4= 40	COT207.0
OTP	P87C51SBBB	0 to +70, Plastic Quad Flat Pack	2.7 V to 5.5 V	0 to 16	SOT307-2
ROM	P80C51SFPN	40 to 195 Pleatic Duel In line Deckage	2.7 V to 5.5 V	0 to 16	SOT129-1
OTP	P87C51SFPN	–40 to +85, Plastic Dual In-line Package	2.7 V to 3.5 V	0 10 10	301129-1
ROM	P80C51SFA A	40 to 195 Plantia Landad Chia Carriar	2.7 V to 5.5 V	0 to 16	SOT187-2
OTP	P87C51SFA A	–40 to +85, Plastic Leaded Chip Carrier	2.7 V 10 5.5 V	0 10 16	301187-2
ROM	P80C51SFBB	–40 to +85, Plastic Quad Flat Pack	2.7 V to 5.5 V	0 to 16	SOT307-2
OTP	P87C51SFBB	-40 to 405, Flastic Quad Flat Fack	2.7 V to 5.5 V	0 10 16	301307-2
ROM	P80C51UBAA	0 to +70, Plastic Leaded Chip Carrier	5 V	0 to 33	SOT187-2
OTP	P87C51UBAA	0 to +70, Plastic Leaded Chip Camer	5 V	0 10 33	301167-2
ROM	P80C51UBPN	0 to +70, Plastic Dual In-line Package	5 V	0 to 33	SOT129-1
OTP	P87C51UBPN	υ το +7υ, Plastic Dual In-line Package	5 V	0 10 33	301129-1
ROM	P80C51UFA A	-40 to +85, Plastic Leaded Chip Carrier	5 V	0 to 33	SOT187-2
OTP	P87C51UFA A	-40 to 403, Flastic Leaded Chip Camer	J V	0 10 33	301101-2

## PART NUMBER DERIVATION

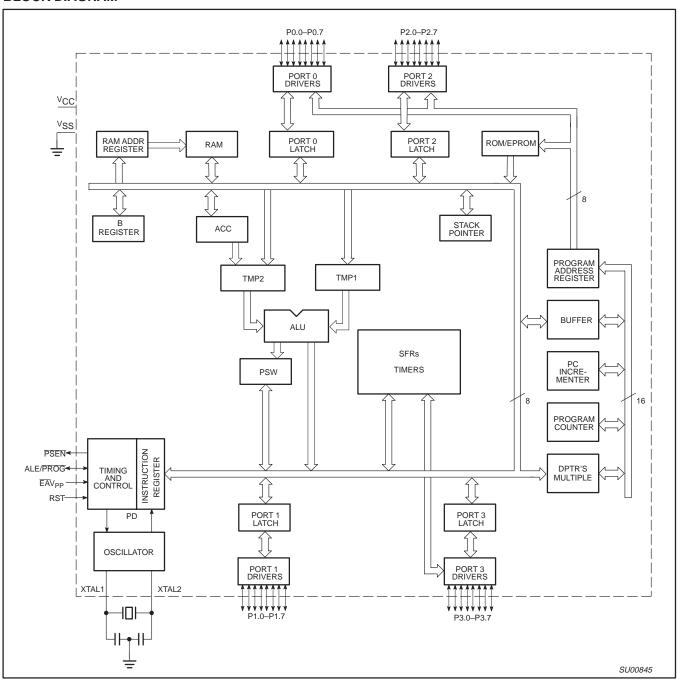
DEVICE NUMBER	DEVICE NUMBER	OPERATING FREQUENCY, MAX (S)	TEMPERATURE RANGE (B)	PACKAGE (AA)
ROM	P80C51	S = 16 MHz	B = 0° to +70°C	AA = PLCC
ROM	P80C52	S = 16 MHz	B = 0° to +70°C	AA = PLCC
OTP	P87C51	U = 33 MHz	$F = -40^{\circ}C$ to $+85^{\circ}C$	BB = PQFP
OTP	P87C52	U = 33 MHz	$F = -40^{\circ}C$ to $+85^{\circ}C$	BB = PQFP

## 80C51/87C51/80C52/87C52

## 80C52/87C52 ORDERING INFORMATION

	MEMORY SIZE 8K × 8	TEMPERATURE RANGE °C AND PACKAGE	VOLTAGE RANGE	FREQ. (MHz)	DWG.#
ROM	P80C52SBPN	0 to +70, Plastic Dual In-line Package	2.7 V to 5.5 V	0 to 16	SOT129-1
ОТР	P87C52SBPN	0 to +70, Plastic Dual In-line Package	2.7 V to 5.5 V	0 10 16	301129-1
ROM	P80C52SBAA	O to 170 Pleatic Leaded Ohio Comics	0.7.1/4- 5.5.1/	0 to 16	007107.0
ОТР	P87C52SBAA	0 to +70, Plastic Leaded Chip Carrier	2.7 V to 5.5 V	0 to 16	SOT187-2
ROM	P80C52SBBB	0 to 170 Plantic Quad Flat Park	0.7.1/4- 5.5.1/	045.40	COT207.0
OTP	P87C52SBBB	0 to +70, Plastic Quad Flat Pack	2.7 V to 5.5 V	0 to 16	SOT307-2
ROM	P80C52SFPN	40 to 105 Plantia Dual la lina Pagliana	2.7 V to 5.5 V	0 to 16	SOT129-1
OTP	P87C52SFPN	–40 to +85, Plastic Dual In-line Package	2.7 V 10 5.5 V	0 10 10	301129-1
ROM	P80C52SFA A	40 to 105 Pleatic Londod Chin Coming	0.7.1/4- 5.5.1/	0 to 16	SOT187-2
OTP	P87C52SFA A	–40 to +85, Plastic Leaded Chip Carrier	2.7 V to 5.5 V	0 to 16	501187-2
ROM	P80C52SFBB	–40 to +85, Plastic Quad Flat Pack	2.7 V to 5.5 V	0 to 16	SOT307-2
OTP	P87C52SFBB	-40 to +65, Flastic Quad Flat Fack	2.7 V to 5.5 V	0 10 16	301307-2
ROM	P80C52UBAA	0 to +70. Plastic Leaded Chip Carrier	5 V	0 to 33	SOT187-2
OTP	P87C52UBAA	0 to +70, Plastic Leaded Chip Carner	5 V	0 10 33	301107-2
ROM	P80C52UBPN	O to 170 Plantia Dual la lina Pagicara	E.V.	0 to 22	COT420.4
ОТР	P87C52UBPN	0 to +70, Plastic Dual In-line Package	5 V	0 to 33	SOT129-1
ROM	P80C52UFA A	-40 to +85, Plastic Leaded Chip Carrier	5 V	0 to 33	SOT187-2
ОТР	P87C52UFA A	-40 to 400, Plastic Leaded Chip Carrier	o v	0 10 33	301101-2

#### **BLOCK DIAGRAM**

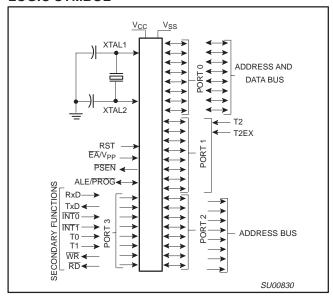


Philips Semiconductors Product specification

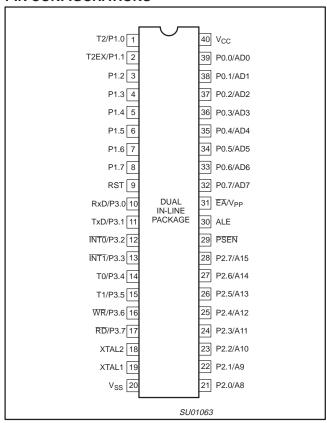
80C51 8-bit microcontroller family 4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V), low power, high speed (33 MHz), 128/256 B RAM

## 80C51/87C51/80C52/87C52

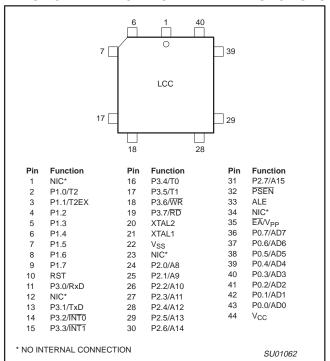
#### LOGIC SYMBOL



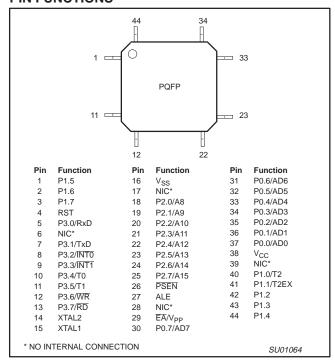
#### **PIN CONFIGURATIONS**



#### PLASTIC LEADED CHIP CARRIER PIN FUNCTIONS



## PLASTIC QUAD FLAT PACK PIN FUNCTIONS



## 80C51/87C51/80C52/87C52

#### **PIN DESCRIPTIONS**

	PII	N NUMB	ER		
MNEMONIC	DIP	LCC	QFP	TYPE	NAME AND FUNCTION
V <sub>SS</sub>	20	22	16	111	Ground: 0 V reference.
V <sub>CC</sub>	40	44	38	li	<b>Power Supply:</b> This is the power supply voltage for normal, idle, and power-down operation.
P0.0–0.7	39–32	43–36	37–30	I/O	Port 0: Port 0 is an open-drain, bidirectional I/O port with Schmitt trigger inputs. Port 0 pins
					that have 1s written to them float and can be used as high-impedance inputs. Port 0 is also the multiplexed low-order address and data bus during accesses to external program and data memory. In this application, it uses strong internal pull-ups when emitting 1s. Port 0 also outputs the code bytes during program verification and received code bytes during EPROM programming. External pull-ups are required during program verification.
P1.0-P1.7	1–8	2–9	40–44, 1–3	I/O	<b>Port 1:</b> Port 1 is an 8-bit bidirectional I/O port with internal pull-ups and Schmitt trigger inputs. Port 1 pins that have 1s written to them are pulled high by the internal pull-ups and can be used as inputs. As inputs, port 1 pins that are externally pulled low will source current because of the internal pull-ups. (See DC Electrical Characteristics: I <sub>IL</sub> ). Port 1 also receives the low-order address byte during program memory verification. Alternate functions for Port 1 include:
	1	2	40	I/O	T2 (P1.0): Timer/Counter 2 external count input/clockout (see Programmable Clock-Out)
1	2	3	41	I	T2EX (P1.1): Timer/Counter 2 Reload/Capture/Direction control
P2.0-P2.7	21–28	24–31	18–25	I/O	Port 2: Port 2 is an 8-bit bidirectional I/O port with internal pull-ups and Schmitt trigger inputs. Port 2 pins that have 1s written to them are pulled high by the internal pull-ups and can be used as inputs. As inputs, port 2 pins that are externally being pulled low will source current because of the internal pull-ups. (See DC Electrical Characteristics: I <sub>IL</sub> ). Port 2 emits the high-order address byte during fetches from external program memory and during accesses to external data memory that use 16-bit addresses (MOVX @DPTR). In this application, it uses strong internal pull-ups when emitting 1s. During accesses to external data memory that use 8-bit addresses (MOV @Ri), port 2 emits the contents of the P2 special function register. Some Port 2 pins receive the high order address bits during EPROM programming and verification.
P3.0-P3.7	10–17	11, 13–19	5, 7–13	I/O	<b>Port 3:</b> Port 3 is an 8-bit bidirectional I/O port with internal pull-ups and Schmitt trigger inputs. Port 3 pins that have 1s written to them are pulled high by the internal pull-ups and can be used as inputs. As inputs, port 3 pins that are externally being pulled low will source current because of the pull-ups. (See DC Electrical Characteristics: I <sub>IL</sub> ). Port 3 also serves the special features of the 80C51 family, as listed below:
	10	11	5	- 1	RxD (P3.0): Serial input port
	11	13	7	0	TxD (P3.1): Serial output port
1	12	14	8	- 1	INTO (P3.2): External interrupt
1	13	15	9	I	INT1 (P3.3): External interrupt
	14	16	10	I	T0 (P3.4): Timer 0 external input
	15	17	11	I	T1 (P3.5): Timer 1 external input
	16	18	12	0	WR (P3.6): External data memory write strobe
	17	19	13	0	RD (P3.7): External data memory read strobe
RST	9	10	4	I	<b>Reset:</b> A high on this pin for two machine cycles while the oscillator is running, resets the device. An internal diffused resistor to V <sub>SS</sub> permits a power-on reset using only an external capacitor to V <sub>CC</sub> .
ALE/PROG	30	33	27	0	Address Latch Enable/Program Pulse: Output pulse for latching the low byte of the address during an access to external memory. In normal operation, ALE is emitted at a constant rate of 1/6 the oscillator frequency, and can be used for external timing or clocking. Note that one ALE pulse is skipped during each access to external data memory. This pin is also the program pulse input (PROG) during EPROM programming. ALE can be disabled by setting SFR auxiliary.0. With this bit set, ALE will be active only during a MOVX instruction.
PSEN	29	32	26	0	Program Store Enable: The read strobe to external program memory. When the device is executing code from the external program memory, PSEN is activated twice each machine cycle, except that two PSEN activations are skipped during each access to external data memory. PSEN is not activated during fetches from internal program memory.
EA/V <sub>PP</sub>	31	35	29	I	External Access Enable/Programming Supply Voltage: EA must be externally held low to enable the device to fetch code from external program memory locations 0000H to 0FFFH. If EA is held high, the device executes from internal program memory unless the program counter contains an address greater than the on-chip ROM/OTP. This pin also receives the 12.75 V programming supply voltage (V <sub>PP</sub> ) during EPROM programming. If security bit 1 is programmed, EA will be internally latched on Reset.
XTAL1	19	21	15	I	Crystal 1: Input to the inverting oscillator amplifier and input to the internal clock generator circuits.
XTAL2	18	20	14	0	Crystal 2: Output from the inverting oscillator amplifier.

NOTE:

To avoid "latch-up" effect at power-on, the voltage on any pin at any time must not be higher than  $V_{CC}$  + 0.5 V or  $V_{SS}$  – 0.5 V, respectively.

## 80C51/87C51/80C52/87C52

Table 1. 80C51/87C51/80C52/87C52 Special Function Registers

SYMBOL	DESCRIPTION	DIRECT ADDRESS	BIT A	DDRESS	, SYMBOI	L, OR ALT	ERNATIV	E PORT	FUNCTIO	N LSB	RESET VALUE
ACC*	Accumulator	E0H	E7	E6	E5	E4	E3	E2	E1	E0	00H
AUXR#	Auxiliary	8EH	-	-	-	<u> </u>	<u> </u>	<u> </u>	l –	AO	xxxxxxx0B
AUXR1#	Auxiliary 1	A2H	_	-	-	LPEP <sup>2</sup>	WUPD	0	-	DPS	xxx000x0B
B*	B register	F0H	F7	F6	F5	F4	F3	F2	F1	F0	00H
DPTR:	Data Pointer (2 bytes)										
DPH	Data Pointer High	83H									00H
DPL	Data Pointer Low	82H									00H
			AF	AE	AD	AC	AB	AA	A9	A8	
IE*	Interrupt Enable	A8H	EA	_	ET2	ES	ET1	EX1	ET0	EX0	0x000000E
	·		BF	BE	BD	ВС	BB	ВА	B9	B8	1
IP*	Interrupt Priority	В8Н	_	_	PT2	PS	PT1	PX1	PT0	PX0	xx000000E
	, ,		B7	B6	B5	B4	B3	B2	B1	B0	1
IPH#	Interrupt Priority High	В7Н	_	_	PT2H	PSH	PT1H	PX1H	PT0H	PX0H	xx000000E
	, , ,		87	86	85	84	83	82	81	80	1
P0*	Port 0	80H	AD7	AD6	AD5	AD4	AD3	AD2	AD1	AD0	FFH
			97	96	95	94	93	92	91	90	1
P1*	Port 1	90H	-		<del>-</del>	<u> </u>	<del></del>	T -	T2EX	T2	FFH
	1 010 1	0011	A7	A6	A5	A4	A3	A2	A1	A0	ł · · · ·
P2*	Port 2	A0H	AD15	AD14	AD13	AD12	AD11	AD10	AD9	AD8	FFH
	1 0112	7.011	B7	B6	B5	B4	B3	B2	B1	B0	1
P3*	Port 3	вон	RD	WR	T1	T0	INT1	INT0	TxD	RxD	FFH
1 0	1 010 0	Don	IND	VVIX	L ''	10		11110	IND	TAD	ł · · · · ·
PCON#1	Power Control	87H	SMOD1	SMOD0	Γ_	POF	GF1	GF0	PD	IDL	00xx0000E
	1 GWGI GGIIGGI	0711	D7	D6	D5	D4	D3	D2	D1	D0	00000002
PSW*	Program Status Word	D0H	CY	AC	F0	RS1	RS0	OV	T _	I P	000000x0E
RACAP2H#	Timer 2 Capture High	CBH	<u> </u>	710	10	1.01	1100	O V		<u> </u>	00H
RACAP2L#	Timer 2 Capture Low	CAH									00H
SADDR#	Slave Address	A9H									00H
SADEN#	Slave Address Mask	В9Н									00H
SBUF	Serial Data Buffer	99H									xxxxxxxxB
020.	001101 2010 201101	00	9F	9E	9D	9C	9B	9A	99	98	70000000
SCON*	Serial Control	98H	SM0/FE	SM1	SM2	REN	TB8	RB8	TI	RI	00H
SP	Stack Pointer	81H	OWO/1 E	OWIT	OIVIZ	IXEIV	100	INDO		131	07H
OI .	Otack i diliter	0111	8F	8E	8D	8C	8B	8A	89	88	0/11
TCON*	Timer Control	88H	TF1	TR1	TF0	TR0	IE1	IT1	IE0	IT0	00H
TCON	Tillier Control	0011	CF	CE	CD	CC	CB	CA	C9	C8	0011
T2CON*	Timor 2 Control	СоП	TF2		RCLK	TCLK	EXEN2			CP/RL2	001
	Timer 2 Made Central	C8H			ROLK		EXEINZ				4
T2MOD# TH0	Timer 2 Mode Control Timer High 0	C9H 8CH	-	_		_		_	T2OE	DCEN	xxxxxxx00B 00H
TH1	Timer High 1	8DH									00H
TH2#	Timer High 2	CDH									00H
TL0	Timer Low 0	8AH									00H
TL1	Timer Low 1	8BH									00H
TL2#	Timer Low 2	CCH									00H
TMOD	Timer Mode	89H	GATE	C/T	M1	MO	GATE	C/T	M1	MO	00H

#### NOTE:

Unused register bits that are not defined should not be set by the user's program. If violated, the device could function incorrectly.

- \* SFRs are bit addressable.
- # SFRs are modified from or added to the 80C51 SFRs.
- Reserved bits.
- 1. Reset value depends on reset source.
- 2. LPEP Low Power EPROM operation (OTP/EPROM only)

## 80C51/87C51/80C52/87C52

#### OSCILLATOR CHARACTERISTICS

XTAL1 and XTAL2 are the input and output, respectively, of an inverting amplifier. The pins can be configured for use as an on-chip oscillator, as shown in the logic symbol.

To drive the device from an external clock source, XTAL1 should be driven while XTAL2 is left unconnected. There are no requirements on the duty cycle of the external clock signal, because the input to the internal clock circuitry is through a divide-by-two flip-flop. However, minimum and maximum high and low times specified in the data sheet must be observed.

#### Reset

A reset is accomplished by holding the RST pin high for at least two machine cycles (24 oscillator periods), while the oscillator is running. To insure a good power-up reset, the RST pin must be high long enough to allow the oscillator time to start up (normally a few milliseconds) plus two machine cycles.

#### **Stop Clock Mode**

The static design enables the clock speed to be reduced down to 0 MHz (stopped). When the oscillator is stopped, the RAM and Special Function Registers retain their values. This mode allows step-by-step utilization and permits reduced system power consumption by lowering the clock frequency down to any value. For lowest power consumption the Power Down mode is suggested.

#### Idle Mode

In idle mode (see Table 2), the CPU puts itself to sleep while all of the on-chip peripherals stay active. The instruction to invoke the idle mode is the last instruction executed in the normal operating mode before the idle mode is activated. The CPU contents, the on-chip RAM, and all of the special function registers remain intact during this mode. The idle mode can be terminated either by any enabled interrupt (at which time the process is picked up at the interrupt service routine and continued), or by a hardware reset which starts the processor in the same manner as a power-on reset.

#### **Power-Down Mode**

To save even more power, a Power Down mode (see Table 2) can be invoked by software. In this mode, the oscillator is stopped and the instruction that invoked Power Down is the last instruction executed. The on-chip RAM and Special Function Registers retain their values down to 2.0 V and care must be taken to return  $V_{CC}$  to the minimum specified operating voltages before the Power Down Mode is terminated.

For the 87C51 and 80C51 either a hardware reset or external interrupt can be used to exit from Power Down. Reset redefines all

the SFRs but does not change the on-chip RAM. An external interrupt allows both the SFRs and the on-chip RAM to retain their values. WUPD (AUXR1.3–Wakeup from Power Down) enables or disables the wakeup from power down with external interrupt. Where:

WUPD = 0 Disable WUPD = 1 Enable

To properly terminate Power Down the reset or external interrupt should not be executed before  $V_{CC}$  is restored to its normal operating level and must be held active long enough for the oscillator to restart and stabilize (normally less than 10 ms).

With an external interrupt, INT0 or INT1 must be enabled and configured as level-sensitive. Holding the pin low restarts the oscillator but bringing the pin back high completes the exit. Once the interrupt is serviced, the next instruction to be executed after RETI will be the one following the instruction that put the device into Power Down.

#### **LPEP**

The eprom array contains some analog circuits that are not required when  $V_{CC}$  is less than 4 V, but are required for a  $V_{CC}$  greater than 4 V. The LPEP bit (AUXR.4), when set, will powerdown these analog circuits resulting in a reduced supply current. This bit should be set ONLY for applications that operate at a  $V_{CC}$  less than 4 V.

#### **Design Consideration**

• When the idle mode is terminated by a hardware reset, the device normally resumes program execution, from where it left off, up to two machine cycles before the internal reset algorithm takes control. On-chip hardware inhibits access to internal RAM in this event, but access to the port pins is not inhibited. To eliminate the possibility of an unexpected write when Idle is terminated by reset, the instruction following the one that invokes Idle should not be one that writes to a port pin or to external memory.

#### **ONCE™ Mode**

The ONCE ("On-Circuit Emulation") Mode facilitates testing and debugging of systems without the device having to be removed from the circuit. The ONCE Mode is invoked by:

- 1. Pull ALE low while the device is in reset and  $\overline{\text{PSEN}}$  is high;
- 2. Hold ALE low as RST is deactivated.

While the device is in ONCE Mode, the Port 0 pins go into a float state, and the other port pins and ALE and PSEN are weakly pulled high. The oscillator circuit remains active. While the device is in this mode, an emulator or test CPU can be used to drive the circuit. Normal operation is restored when a normal reset is applied.

Table 2. External Pin Status During Idle and Power-Down Modes

MODE	PROGRAM MEMORY	ALE	PSEN	PORT 0	PORT 1	PORT 2	PORT 3
Idle	Internal	1	1	Data	Data	Data	Data
Idle	External	1	1	Float	Data	Address	Data
Power-down	Internal	0	0	Data	Data	Data	Data
Power-down	External	0	0	Float	Data	Data	Data

## 80C51/87C51/80C52/87C52

#### **Programmable Clock-Out**

A 50% duty cycle clock can be programmed to come out on P1.0. This pin, besides being a regular I/O pin, has two alternate functions. It can be programmed:

- 1. to input the external clock for Timer/Counter 2, or
- to output a 50% duty cycle clock ranging from 61 Hz to 4 MHz at a 16 MHz operating frequency.

To configure the Timer/Counter 2 as a clock generator, bit C/T2 (in T2CON) must be cleared and bit T20E in T2MOD must be set. Bit TR2 (T2CON.2) also must be set to start the timer.

The Clock-Out frequency depends on the oscillator frequency and the reload value of Timer 2 capture registers (RCAP2H, RCAP2L) as shown in this equation:

Where:

(RCAP2H,RCAP2L) = the content of RCAP2H and RCAP2L taken as a 16-bit unsigned integer.

In the Clock-Out mode Timer 2 roll-overs will not generate an interrupt. This is similar to when it is used as a baud-rate generator. It is possible to use Timer 2 as a baud-rate generator and a clock generator simultaneously. Note, however, that the baud-rate and the Clock-Out frequency will be the same.

#### **TIMER 2 OPERATION**

#### Timer 2

Timer 2 is a 16-bit Timer/Counter which can operate as either an event timer or an event counter, as selected by  $C/\overline{T}2^*$  in the special function register T2CON (see Figure 1). Timer 2 has three operating modes:Capture, Auto-reload (up or down counting) ,and Baud Rate Generator, which are selected by bits in the T2CON as shown in Table 3.

#### Capture Mode

In the capture mode there are two options which are selected by bit EXEN2 in T2CON. If EXEN2=0, then timer 2 is a 16-bit timer or counter (as selected by C/T2\* in T2CON) which, upon overflowing sets bit TF2, the timer 2 overflow bit. This bit can be used to generate an interrupt (by enabling the Timer 2 interrupt bit in the IE register). If EXEN2= 1, Timer 2 operates as described above, but with the added feature that a 1- to -0 transition at external input T2EX causes the current value in the Timer 2 registers, TL2 and

TH2, to be captured into registers RCAP2L and RCAP2H, respectively. In addition, the transition at T2EX causes bit EXF2 in T2CON to be set, and EXF2 like TF2 can generate an interrupt (which vectors to the same location as Timer 2 overflow interrupt. The Timer 2 interrupt service routine can interrogate TF2 and EXF2 to determine which event caused the interrupt). The capture mode is illustrated in Figure 2 (There is no reload value for TL2 and TH2 in this mode. Even when a capture event occurs from T2EX, the counter keeps on counting T2EX pin transitions or osc/12 pulses.).

#### Auto-Reload Mode (Up or Down Counter)

In the 16-bit auto-reload mode, Timer 2 can be configured (as either a timer or counter (C/T2\* in T2CON)) then programmed to count up or down. The counting direction is determined by bit DCEN (Down Counter Enable) which is located in the T2MOD register (see Figure 3). When reset is applied the DCEN=0 which means Timer 2 will default to counting up. If DCEN bit is set, Timer 2 can count up or down depending on the value of the T2EX pin.

Figure 4 shows Timer 2 which will count up automatically since DCEN=0. In this mode there are two options selected by bit EXEN2 in T2CON register. If EXEN2=0, then Timer 2 counts up to 0FFFFH and sets the TF2 (Overflow Flag) bit upon overflow. This causes the Timer 2 registers to be reloaded with the 16-bit value in RCAP2L and RCAP2H. The values in RCAP2L and RCAP2H are preset by software means.

If EXEN2=1, then a 16-bit reload can be triggered either by an overflow or by a 1-to-0 transition at input T2EX. This transition also sets the EXF2 bit. The Timer 2 interrupt, if enabled, can be generated when either TF2 or EXF2 are 1.

In Figure 5 DCEN=1 which enables Timer 2 to count up or down. This mode allows pin T2EX to control the direction of count. When a logic 1 is applied at pin T2EX Timer 2 will count up. Timer 2 will overflow at 0FFFFH and set the TF2 flag, which can then generate an interrupt, if the interrupt is enabled. This timer overflow also causes the 16–bit value in RCAP2L and RCAP2H to be reloaded into the timer registers TL2 and TH2.

When a logic 0 is applied at pin T2EX this causes Timer 2 to count down. The timer will underflow when TL2 and TH2 become equal to the value stored in RCAP2L and RCAP2H. Timer 2 underflow sets the TF2 flag and causes 0FFFFH to be reloaded into the timer registers TL2 and TH2.

The external flag EXF2 toggles when Timer 2 underflows or overflows. This EXF2 bit can be used as a 17th bit of resolution if needed. The EXF2 flag does not generate an interrupt in this mode of operation.

Table 3. Timer 2 Operating Modes

RCLK + TCLK	CP/RL2	TR2	MODE
0	0	1	16-bit Auto-reload
0	1	1	16-bit Capture
1	Х	1	Baud rate generator
Х	Х	0	(off)

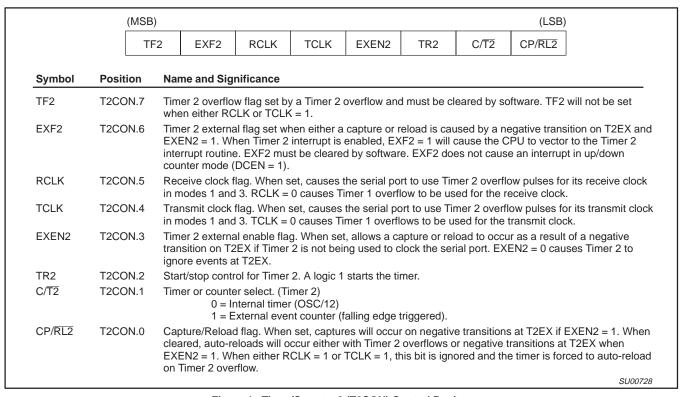


Figure 1. Timer/Counter 2 (T2CON) Control Register

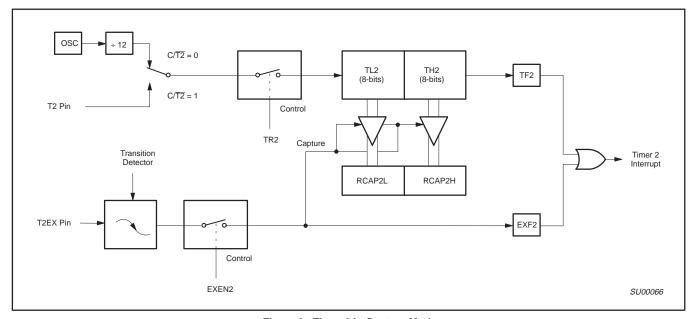


Figure 2. Timer 2 in Capture Mode

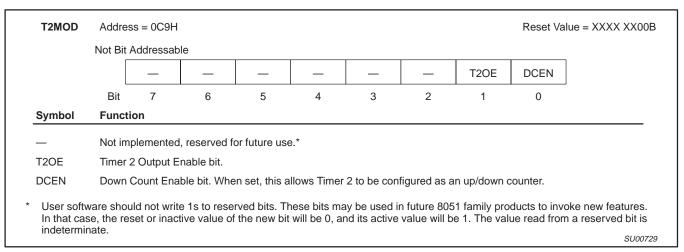


Figure 3. Timer 2 Mode (T2MOD) Control Register

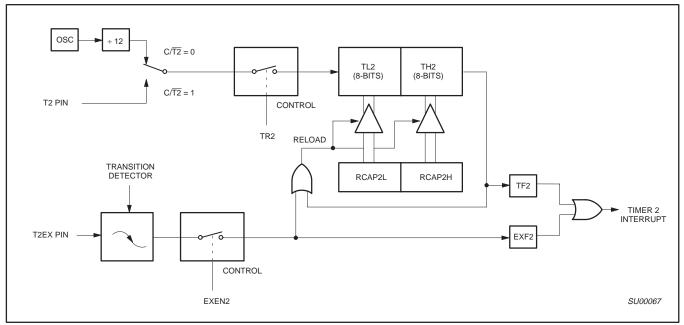


Figure 4. Timer 2 in Auto-Reload Mode (DCEN = 0)

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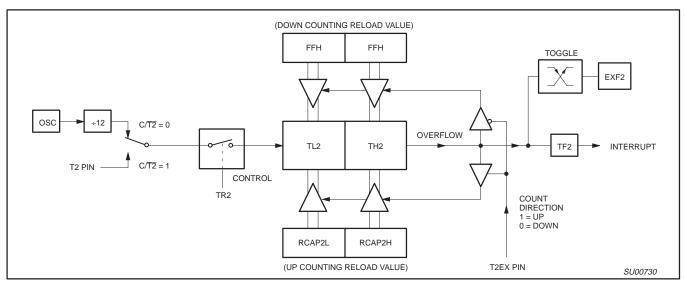


Figure 5. Timer 2 Auto Reload Mode (DCEN = 1)

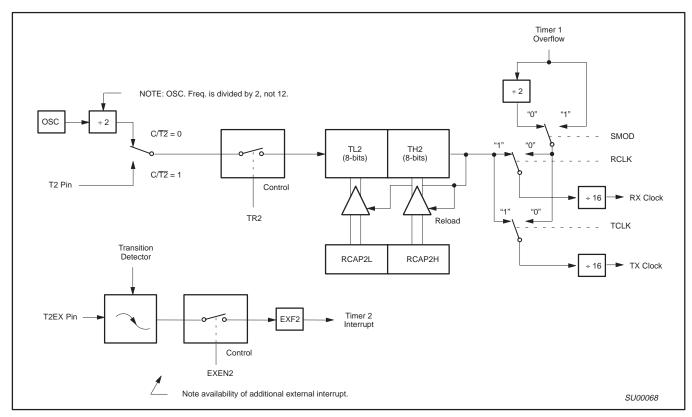


Figure 6. Timer 2 in Baud Rate Generator Mode

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#### **Baud Rate Generator Mode**

Bits TCLK and/or RCLK in T2CON (Table 3) allow the serial port transmit and receive baud rates to be derived from either Timer 1 or Timer 2. When TCLK= 0, Timer 1 is used as the serial port transmit baud rate generator. When TCLK= 1, Timer 2 is used as the serial port transmit baud rate generator. RCLK has the same effect for the serial port receive baud rate. With these two bits, the serial port can have different receive and transmit baud rates – one generated by Timer 1, the other by Timer 2.

Figure 6 shows the Timer 2 in baud rate generation mode. The baud rate generation mode is like the auto-reload mode, in that a rollover in TH2 causes the Timer 2 registers to be reloaded with the 16-bit value in registers RCAP2H and RCAP2L, which are preset by software.

The baud rates in modes 1 and 3 are determined by Timer 2's overflow rate given below:

Modes 1 and 3 Baud Rates = 
$$\frac{\text{Timer 2 Overflow Rate}}{16}$$

The timer can be configured for either "timer" or "counter" operation. In many applications, it is configured for "timer" operation (C/T2\*=0). Timer operation is different for Timer 2 when it is being used as a baud rate generator.

Usually, as a timer it would increment every machine cycle (i.e., 1/12 the oscillator frequency). As a baud rate generator, it increments every state time (i.e., 1/2 the oscillator frequency). Thus the baud rate formula is as follows:

Modes 1 and 3 Baud Rates =

$$\frac{\text{Oscillator Frequency}}{[32 \times [65536 - (\text{RCAP2H}, \text{RCAP2L})]]}$$

Where: (RCAP2H, RCAP2L)= The content of RCAP2H and RCAP2L taken as a 16-bit unsigned integer.

The Timer 2 as a baud rate generator mode shown in Figure 6, is valid only if RCLK and/or TCLK = 1 in T2CON register. Note that a rollover in TH2 does not set TF2, and will not generate an interrupt. Thus, the Timer 2 interrupt does not have to be disabled when Timer 2 is in the baud rate generator mode. Also if the EXEN2 (T2 external enable flag) is set, a 1-to-0 transition in T2EX (Timer/counter 2 trigger input) will set EXF2 (T2 external flag) but will not cause a reload from (RCAP2H, RCAP2L) to (TH2,TL2). Therefore when Timer 2 is in use as a baud rate generator, T2EX can be used as an additional external interrupt, if needed.

When Timer 2 is in the baud rate generator mode, one should not try to read or write TH2 and TL2. As a baud rate generator, Timer 2 is incremented every state time (osc/2) or asynchronously from pin T2;

under these conditions, a read or write of TH2 or TL2 may not be accurate. The RCAP2 registers may be read, but should not be written to, because a write might overlap a reload and cause write and/or reload errors. The timer should be turned off (clear TR2) before accessing the Timer 2 or RCAP2 registers.

Table 4 shows commonly used baud rates and how they can be obtained from Timer 2.

Table 4. Timer 2 Generated Commonly Used Baud Rates

Baud Rate	Oco Erog	Timer 2			
Baud Rate	Osc Freq	RCAP2H	RCAP2L		
375 K	12 MHz	FF	FF		
9.6 K	12 MHz	FF	D9		
2.8 K	12 MHz	FF	B2		
2.4 K	12 MHz	FF	64		
1.2 K	12 MHz	FE	C8		
300	12 MHz	FB	1E		
110	12 MHz	F2	AF		
300	6 MHz	FD	8F		
110	6 MHz	F9	57		

## **Summary Of Baud Rate Equations**

Timer 2 is in baud rate generating mode. If Timer 2 is being clocked through pin T2(P1.0) the baud rate is:

Baud Rate = 
$$\frac{\text{Timer 2 Overflow Rate}}{16}$$

If Timer 2 is being clocked internally, the baud rate is:

Baud Rate = 
$$\frac{f_{OSC}}{[32 \times [65536 - (RCAP2H, RCAP2L)]]}$$

Where fosc= Oscillator Frequency

To obtain the reload value for RCAP2H and RCAP2L, the above equation can be rewritten as:

RCAP2H, RCAP2L = 
$$65536 - \left(\frac{f_{OSC}}{32 \times Baud \ Rate}\right)$$

### Timer/Counter 2 Set-up

Except for the baud rate generator mode, the values given for T2CON do not include the setting of the TR2 bit. Therefore, bit TR2 must be set, separately, to turn the timer on. See Table 5 for set-up of Timer 2 as a timer. Also see Table 6 for set-up of Timer 2 as a counter.

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Table 5. Timer 2 as a Timer

MODE	T2CON			
MODE	INTERNAL CONTROL (Note 1)	EXTERNAL CONTROL (Note 2)		
16-bit Auto-Reload	00H	08H		
16-bit Capture	01H	09H		
Baud rate generator receive and transmit same baud rate	34H	36H		
Receive only	24H	26H		
Transmit only	14H	16H		

#### Table 6. Timer 2 as a Counter

MODE	TMOD			
MODE	INTERNAL CONTROL (Note 1)	EXTERNAL CONTROL (Note 2)		
16-bit	02H	0AH		
Auto-Reload	03H	0BH		

#### NOTES:

- 1. Capture/reload occurs only on timer/counter overflow.
- 2. Capture/reload occurs on timer/counter overflow and a 1-to-0 transition on T2EX (P1.1) pin except when Timer 2 is used in the baud rate generator mode.

#### **Enhanced UART**

The UART operates in all of the usual modes that are described in the first section of *Data Handbook IC20, 80C51-Based 8-Bit Microcontrollers*. In addition the UART can perform framing error detect by looking for missing stop bits, and automatic address recognition. The UART also fully supports multiprocessor communication.

When used for framing error detect the UART looks for missing stop bits in the communication. A missing bit will set the FE bit in the SCON register. The FE bit shares the SCON.7 bit with SM0 and the function of SCON.7 is determined by PCON.6 (SMOD0) (see Figure 7). If SMOD0 is set then SCON.7 functions as FE. SCON.7 functions as SM0 when SMOD0 is cleared. When used as FE SCON.7 can only be cleared by software. Refer to Figure 8.

#### **Automatic Address Recognition**

Automatic Address Recognition is a feature which allows the UART to recognize certain addresses in the serial bit stream by using hardware to make the comparisons. This feature saves a great deal of software overhead by eliminating the need for the software to examine every serial address which passes by the serial port. This feature is enabled by setting the SM2 bit in SCON. In the 9 bit UART modes, mode 2 and mode 3, the Receive Interrupt flag (RI) will be automatically set when the received byte contains either the "Given" address or the "Broadcast" address. The 9 bit mode requires that the 9th information bit is a 1 to indicate that the received information is an address and not data. Automatic address recognition is shown in Figure 9.

The 8 bit mode is called Mode 1. In this mode the RI flag will be set if SM2 is enabled and the information received has a valid stop bit following the 8 address bits and the information is either a Given or Broadcast address.

Mode 0 is the Shift Register mode and SM2 is ignored.

Using the Automatic Address Recognition feature allows a master to selectively communicate with one or more slaves by invoking the Given slave address or addresses. All of the slaves may be contacted by using the Broadcast address. Two special Function Registers are used to define the slave's address, SADDR, and the address mask, SADEN. SADEN is used to define which bits in the

SADDR are to b used and which bits are "don't care". The SADEN mask can be logically ANDed with the SADDR to create the "Given" address which the master will use for addressing each of the slaves. Use of the Given address allows multiple slaves to be recognized while excluding others. The following examples will help to show the versatility of this scheme:

Slave 0	SADDR	=	1100 0000
	0, 12 = 11	=	<u>1111 1101</u>
	Given	=	1100 00X0
Slave 1	SADDR	=	1100 0000
	SADEN	=	<u>1111 1110</u>
	Given	_	1100 000X

In the above example SADDR is the same and the SADEN data is used to differentiate between the two slaves. Slave 0 requires a 0 in bit 0 and it ignores bit 1. Slave 1 requires a 0 in bit 1 and bit 0 is ignored. A unique address for Slave 0 would be 1100 0010 since slave 1 requires a 0 in bit 1. A unique address for slave 1 would be 1100 0001 since a 1 in bit 0 will exclude slave 0. Both slaves can be selected at the same time by an address which has bit 0 = 0 (for slave 0) and bit 1 = 0 (for slave 1). Thus, both could be addressed with 1100 0000.

In a more complex system the following could be used to select slaves 1 and 2 while excluding slave 0:

Slave 0	SADDR	=	1100 0000
	SADEN	=	<u>1111 1001</u>
	Given	=	1100 0XX0
Slave 1	SADDR	=	1110 0000
	SADEN	=	<u>1111 1010</u>
	Given	=	1110 0X0X
Slave 2	SADDR	=	1110 0000
	SADEN	=	<u>1111 1100</u>
	Given	=	1110 00XX

In the above example the differentiation among the 3 slaves is in the lower 3 address bits. Slave 0 requires that bit 0=0 and it can be uniquely addressed by 1110 0110. Slave 1 requires that bit 1=0 and it can be uniquely addressed by 1110 and 0101. Slave 2 requires that bit 2=0 and its unique address is 1110 0011. To select Slaves 0

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and 1 and exclude Slave 2 use address 1110 0100, since it is necessary to make bit 2 = 1 to exclude slave 2.

The Broadcast Address for each slave is created by taking the logical OR of SADDR and SADEN. Zeros in this result are trended as don't-cares. In most cases, interpreting the don't-cares as ones, the broadcast address will be FF hexadecimal.

Upon reset SADDR (SFR address 0A9H) and SADEN (SFR address 0B9H) are leaded with 0s. This produces a given address of all "don't cares" as well as a Broadcast address of all "don't cares". This effectively disables the Automatic Addressing mode and allows the microcontroller to use standard 80C51 type UART drivers which do not make use of this feature.

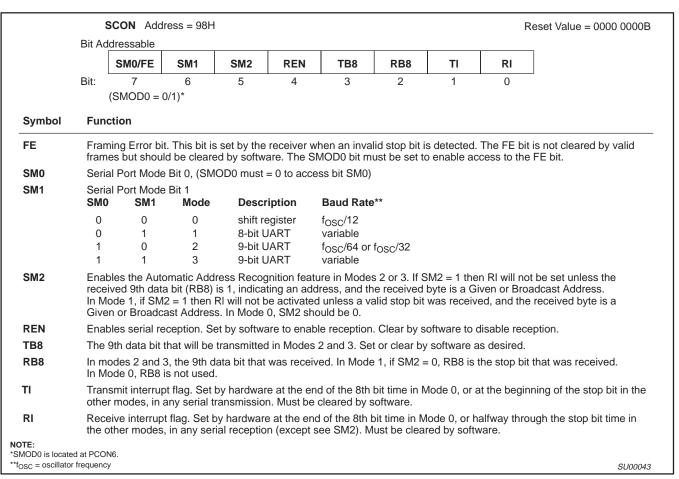


Figure 7. SCON: Serial Port Control Register

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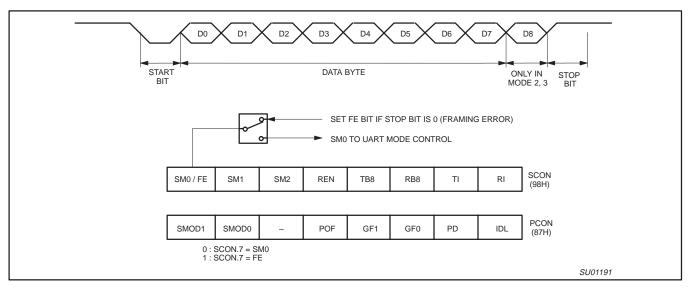


Figure 8. UART Framing Error Detection

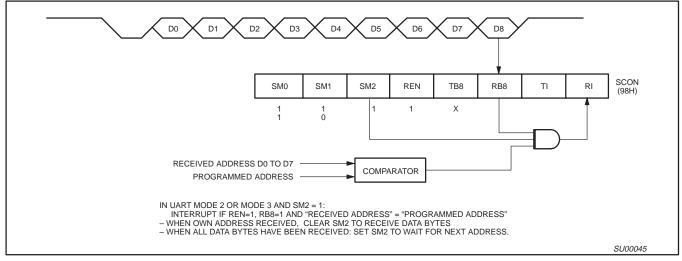


Figure 9. UART Multiprocessor Communication, Automatic Address Recognition

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#### **Interrupt Priority Structure**

The 80C51/87C51 and 80C52/87C52 have a 6-source four-level interrupt structure. They are the IE, IP and IPH. (See Figures 10, 11, and 12.) The IPH (Interrupt Priority High) register that makes the four-level interrupt structure possible. The IPH is located at SFR address B7H. The structure of the IPH register and a description of its bits is shown in Figure 12.

The function of the IPH SFR is simple and when combined with the IP SFR determines the priority of each interrupt. The priority of each interrupt is determined as shown in the following table:

PRIORI	TY BITS	INTERRUPT PRIORITY LEVEL
IPH.x	IP.x	INTERROPT PRIORITT LEVEL
0	0	Level 0 (lowest priority)
0	1	Level 1
1	0	Level 2
1	1	Level 3 (highest priority)

An interrupt will be serviced as long as an interrupt of equal or higher priority is not already being serviced. If an interrupt of equal or higher level priority is being serviced, the new interrupt will wait until it is finished before being serviced. If a lower priority level interrupt is being serviced, it will be stopped and the new interrupt serviced. When the new interrupt is finished, the lower priority level interrupt that was stopped will be completed.

Table 7. Interrupt Table

SOURCE	POLLING PRIORITY	REQUEST BITS	HARDWARE CLEAR?	VECTOR ADDRESS
X0	1	IE0	N (L) <sup>1</sup> Y (T) <sup>2</sup>	03H
T0	2	TP0	Υ	0BH
X1	3	IE1	N (L) Y (T)	13H
T1	4	TF1	Υ	1BH
SP	5	RI, TI	N	23H
T2	6	TF2, EXF2	N	2BH

#### NOTES:

- 1. L = Level activated
- 2. T = Transition activated

		7	6	5	4	3	2	1	0
	IE (0A8H)	EA	_	ET2	ES	ET1	EX1	ET0	EX0
			Bit = 1 ena Bit = 0 dis		nterrupt.				
BIT	SYMBOL	FUNC	TION						
IE.7	EA					rrupts are earing its			each inte
IE.6	_	Not im	plemente	d. Reserv	ed for futu	ire use.			
IE.5	ET2	Timer	2 interrup	t enable b	it.				
IE.4	ES	Serial	Port inter	upt enabl	e bit.				
IE.3	ET1	Timer	1 interrup	t enable b	it.				
IE.2	EX1	Extern	al interru	t 1 enable	e bit.				
IE.1	ET0	Timer	0 interrup	t enable b	it.				
IE.0	EX0	Extern	al interru	t 0 enable	e bit.				

Figure 10. IE Registers

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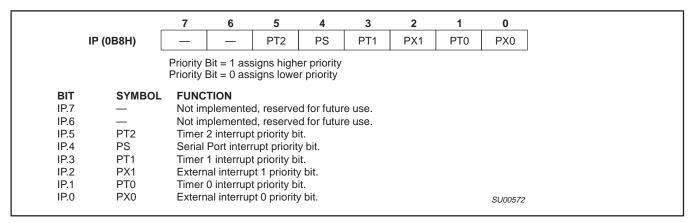


Figure 11. IP Registers

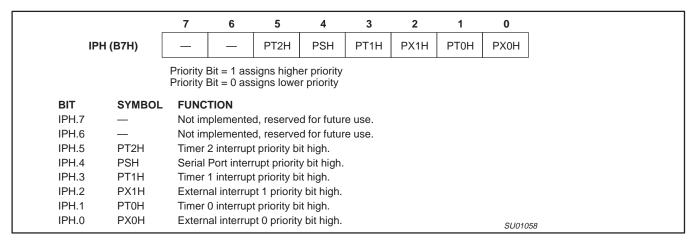


Figure 12. IPH Registers

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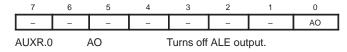
#### Reduced EMI

All port pins of the 8xC51 and 8xC52 have slew rate controlled outputs. This is to limit noise generated by quickly switching output signals. The slew rate is factory set to approximately 10 ns rise and fall times.

#### **Reduced EMI Mode**

The AO bit (AUXR.0) in the AUXR register when set disables the ALE output.

#### AUXR (8EH)



#### **Dual DPTR**

The dual DPTR structure (see Figure 13) enables a way to specify the address of an external data memory location. There are two 16-bit DPTR registers that address the external memory, and a single bit called DPS = AUXR1/bit0 that allows the program code to switch between them.

New Register Name: AUXR1#

SFR Address: A2HReset Value: xxx000x0B

#### AUXR1 (A2H)

7	6	5	4	3	2	1	0
-	-	-	LPEP	WUPD	0	-	DPS

Where:

 $\label{eq:decomposition} \text{DPS} = \text{AUXR1/bit0} = \text{Switches between DPTR0} \text{ and DPTR1}.$ 

Select Reg	DPS
DPTR0	0
DPTR1	1

The DPS bit status should be saved by software when switching between DPTR0 and DPTR1.

Note that bit 2 is not writable and is always read as a zero. This allows the DPS bit to be quickly toggled simply by executing an INC DPTR instruction without affecting the WOPD or LPEP bits.

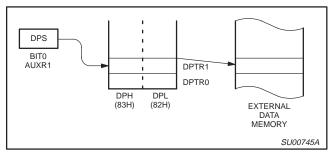


Figure 13.

#### **DPTR Instructions**

The instructions that refer to DPTR refer to the data pointer that is currently selected using the AUXR1/bit 0 register. The six instructions that use the DPTR are as follows:

INC DPTR	Increments the data pointer by 1
MOV DPTR, #data16	Loads the DPTR with a 16-bit constant
MOV A, @ A+DPTR	Move code byte relative to DPTR to ACC
MOVX A, @ DPTR	Move external RAM (16-bit address) to ACC
MOVX @ DPTR , A	Move ACC to external RAM (16-bit address)
JMP @ A + DPTR	Jump indirect relative to DPTR

The data pointer can be accessed on a byte-by-byte basis by specifying the low or high byte in an instruction which accesses the SFRs. See application note AN458 for more details.

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## **ABSOLUTE MAXIMUM RATINGS**1, 2, 3

PARAMETER	RATING	UNIT
Operating temperature under bias	0 to +70 or -40 to +85	°C
Storage temperature range	-65 to +150	°C
Voltage on EA/V <sub>PP</sub> pin to V <sub>SS</sub>	0 to +13.0	V
Voltage on any other pin to V <sub>SS</sub>	-0.5 to +6.5	V
Maximum I <sub>OL</sub> per I/O pin	15	mA
Power dissipation (based on package heat transfer limitations, not device power consumption)	1.5	W

#### NOTES:

- 1. Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any conditions other than those described in the AC and DC Electrical Characteristics section of this specification is not implied.
- This product includes circuitry specifically designed for the protection of its internal devices from the damaging effects of excessive static charge. Nonetheless, it is suggested that conventional precautions be taken to avoid applying greater than the rated maximum.
   Parameters are valid over operating temperature range unless otherwise specified. All voltages are with respect to V<sub>SS</sub> unless otherwise
- Parameters are valid over operating temperature range unless otherwise specified. All voltages are with respect to V<sub>SS</sub> unless otherwise noted.

#### **AC ELECTRICAL CHARACTERISTICS**

 $T_{amb} = 0$ °C to +70°C or -40°C to +85°C

			CLOCK FR RANG		
SYMBOL	FIGURE	PARAMETER	MIN	MAX	UNIT
1/t <sub>CLCL</sub>	29	Oscillator frequency Speed versions : S (16 MHz) U (33 MHz)	0		MHz MHz

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#### DC ELECTRICAL CHARACTERISTICS

 $T_{amb} = 0^{\circ}C$  to +70°C or -40°C to +85°C,  $V_{CC} = 2.7$  V to 5.5 V,  $V_{SS} = 0$  V (16 MHz devices)

0)/440.01	DADAMETED	TEST					
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP <sup>1</sup>	MAX	UNIT	
M	Lagrand Lagrand and 11	4.0 V < V <sub>CC</sub> < 5.5 V	-0.5		0.2 V <sub>CC</sub> -0.1	V	
$V_{IL}$	Input low voltage <sup>11</sup>	2.7 V <v<sub>CC&lt; 4.0 V</v<sub>	-0.5		0.7	V	
V <sub>IH</sub>	Input high voltage (ports 0, 1, 2, 3, EA)		0.2 V <sub>CC</sub> +0.9		V <sub>CC</sub> +0.5	V	
V <sub>IH1</sub>	Input high voltage, XTAL1, RST <sup>11</sup>		0.7 V <sub>CC</sub>		V <sub>CC</sub> +0.5	V	
V <sub>OL</sub>	Output low voltage, ports 1, 2, 8	$V_{CC} = 2.7 \text{ V}$ $I_{OL} = 1.6 \text{ mA}^2$			0.4	V	
V <sub>OL1</sub>	Output low voltage, port 0, ALE, PSEN8, 7	$V_{CC} = 2.7 \text{ V}$ $I_{OL} = 3.2 \text{ mA}^2$			0.4	V	
V <sub>ОН</sub>	Output himb vallege posts 4, 0, 9,3	$V_{CC} = 2.7 \text{ V}$ $I_{OH} = -20 \mu\text{A}$	V <sub>CC</sub> - 0.7			V	
	Output high voltage, ports 1, 2, 3 <sup>3</sup>	V <sub>CC</sub> = 4.5 V I <sub>OH</sub> = -30 μA	V <sub>CC</sub> - 0.7			V	
V <sub>OH1</sub>	Output high voltage (port 0 in external bus mode), ALE <sup>9</sup> , PSEN <sup>3</sup>	$V_{CC} = 2.7 \text{ V}$ $I_{OH} = -3.2 \text{ mA}$	V <sub>CC</sub> - 0.7			V	
I <sub>IL</sub>	Logical 0 input current, ports 1, 2, 3	V <sub>IN</sub> = 0.4 V	-1		-50	μΑ	
I <sub>TL</sub>	Logical 1-to-0 transition current, ports 1, 2, 36	V <sub>IN</sub> = 2.0 V See note 4			-650	μА	
ILI	Input leakage current, port 0	$0.45 < V_{IN} < V_{CC} - 0.3$			±10	μΑ	
Icc	Power supply current (see Figure 21): Active mode @ 16 MHz Idle mode @ 16 MHz Power-down mode or clock stopped (see Figure 25 for conditions)	See note 5 $T_{amb} = 0^{\circ}C \text{ to } 70^{\circ}C$ $T_{amb} = -40^{\circ}C \text{ to } +85^{\circ}C$		3	50 75	μΑ μΑ μΑ μΑ	
R <sub>RST</sub>	Internal reset pull-down resistor		40		225	kΩ	
C <sub>IO</sub>	Pin capacitance <sup>10</sup> (except EA)				15	pF	

#### NOTES:

- 1. Typical ratings are not guaranteed. The values listed are at room temperature, 5 V.
- 2. Capacitive loading on ports 0 and 2 may cause spurious noise to be superimposed on the VOLs of ALE and ports 1 and 3. The noise is due to external bus capacitance discharging into the port 0 and port 2 pins when these pins make 1-to-0 transitions during bus operations. In the worst cases (capacitive loading > 100 pF), the noise pulse on the ALE pin may exceed 0.8 V. In such cases, it may be desirable to qualify ALE with a Schmitt Trigger, or use an address latch with a Schmitt Trigger STROBE input. IoL can exceed these conditions provided that no single output sinks more than 5 mA and no more than two outputs exceed the test conditions
- 3. Capacitive loading on ports 0 and 2 may cause the  $V_{OH}$  on ALE and  $\overline{PSEN}$  to momentarily fall below the  $V_{CC}$ -0.7 specification when the address bits are stabilizing.
- Pins of ports 1, 2 and 3 source a transition current when they are being externally driven from 1 to 0. The transition current reaches its maximum value when V<sub>IN</sub> is approximately 2 V.
- See Figures 22 through 25 for I<sub>CC</sub> test conditions.

 $I_{CC} = 0.9 \times FREQ. + 1.1 \text{ mA}$ 

- Idle mode:  $I_{CC} = 0.18 \times FREQ. +1.01$  mA; See Figure 21. 6. This value applies to  $T_{amb} = 0^{\circ}C$  to  $+70^{\circ}C$ . For  $T_{amb} = -40^{\circ}C$  to  $+85^{\circ}C$ ,  $I_{TL} = -750$   $\mu$ A.
- Load capacitance for port 0, ALE, and  $\overline{PSEN} = 100 \text{ pF}$ , load capacitance for all other outputs = 80 pF.
- 8. Under steady state (non-transient) conditions,  $I_{OL}$  must be externally limited as follows: Maximum I<sub>OL</sub> per port pin: 15 mA (\*NOTE: This is 85°C specification.)

Maximum I<sub>OL</sub> per 8-bit port: 26 mA

Maximum total I<sub>OL</sub> for all outputs: 71 mA

If  $I_{OL}$  exceeds the test condition,  $V_{OL}$  may exceed the related specification. Pins are not guaranteed to sink current greater than the listed test conditions.

- ALE is tested to V<sub>OH1</sub>, except when ALE is off then V<sub>OH</sub> is the voltage specification.
- 10. Pin capacitance is characterized but not tested. Pin capacitance is less than 25 pF. Pin capacitance of ceramic package is less than 15 pF (except EA is 25 pF).
- 11. To improve noise rejection a nominal 100 ns glitch rejection circuitry has been added to the RST pin, and a nominal 15 ns glitch rejection circuitry has been added to the INTO and INTO pins. Previous devices provided only an inherent 5 ns of glitch rejection.

## 80C51/87C51/80C52/87C52

#### DC ELECTRICAL CHARACTERISTICS

 $T_{amb} = 0$ °C to +70°C or -40°C to +85°C, 33 MHz devices; 5 V ±10%;  $V_{SS} = 0$  V

OVMDOL	DADAMETED	TEST					
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP <sup>1</sup> MAX		UNIT	
V <sub>IL</sub>	Input low voltage <sup>11</sup>	4.5 V < V <sub>CC</sub> < 5.5 V	-0.5		0.2 V <sub>CC</sub> -0.1	V	
V <sub>IH</sub>	Input high voltage (ports 0, 1, 2, 3, EA)		0.2 V <sub>CC</sub> +0.9		V <sub>CC</sub> +0.5	V	
V <sub>IH1</sub>	Input high voltage, XTAL1, RST <sup>11</sup>		0.7 V <sub>CC</sub>		V <sub>CC</sub> +0.5	V	
V <sub>OL</sub>	Output low voltage, ports 1, 2, 3 8	$V_{CC} = 4.5 \text{ V}$ $I_{OL} = 1.6 \text{mA}^2$			0.4	V	
V <sub>OL1</sub>	Output low voltage, port 0, ALE, PSEN 7, 8	$V_{CC} = 4.5 \text{ V}$ $I_{OL} = 3.2 \text{mA}^2$			0.4	V	
V <sub>OH</sub>	Output high voltage, ports 1, 2, 3 <sup>3</sup>	$V_{CC} = 4.5 \text{ V}$ $I_{OH} = -30 \mu \text{A}$	V <sub>CC</sub> - 0.7			V	
V <sub>OH1</sub>	Output high voltage (port 0 in external bus mode), ALE <sup>9</sup> , PSEN <sup>3</sup>	$V_{CC} = 4.5 \text{ V}$ $I_{OH} = -3.2 \text{mA}$	V <sub>CC</sub> - 0.7			V	
I <sub>IL</sub>	Logical 0 input current, ports 1, 2, 3	V <sub>IN</sub> = 0.4 V	-1		-50	μΑ	
I <sub>TL</sub>	Logical 1-to-0 transition current, ports 1, 2, 3 <sup>6</sup>	V <sub>IN</sub> = 2.0 V See note 4			-650	μΑ	
I <sub>LI</sub>	Input leakage current, port 0	$0.45 < V_{IN} < V_{CC} - 0.3$			±10	μΑ	
I <sub>CC</sub>	Power supply current (see Figure 21): Active mode (see Note 5) Idle mode (see Note 5)	See note 5					
	Power-down mode or clock stopped (see Fig- ure 25 for conditions)	$T_{amb} = 0^{\circ}C \text{ to } 70^{\circ}C$ $T_{amb} = -40^{\circ}C \text{ to } +85^{\circ}C$		3	50 75	μA μA	
R <sub>RST</sub>	Internal reset pull-down resistor		40		225	kΩ	
C <sub>IO</sub>	Pin capacitance <sup>10</sup> (except <del>EA</del> )				15	pF	

#### NOTES:

- 1. Typical ratings are not guaranteed. The values listed are at room temperature, 5 V.
- Capacitive loading on ports 0 and 2 may cause spurious noise to be superimposed on the VOLs of ALE and ports 1 and 3. The noise is due to external bus capacitance discharging into the port 0 and port 2 pins when these pins make 1-to-0 transitions during bus operations. In the worst cases (capacitive loading > 100 pF), the noise pulse on the ALE pin may exceed 0.8 V. In such cases, it may be desirable to qualify ALE with a Schmitt Trigger, or use an address latch with a Schmitt Trigger STROBE input. IOL can exceed these conditions provided that no single output sinks more than 5mA and no more than two outputs exceed the test conditions.
- 3. Capacitive loading on ports 0 and 2 may cause the  $V_{OH}$  on ALE and PSEN to momentarily fall below the  $V_{CC}$ -0.7 specification when the address bits are stabilizing.
- Pins of ports 1, 2 and 3 source a transition current when they are being externally driven from 1 to 0. The transition current reaches its maximum value when  $V_{\mbox{\scriptsize IN}}$  is approximately 2 V.
- 5. See Figures 22 through 25 for I<sub>CC</sub> test conditions.

- Active mode:  $I_{CC(MAX)} = 0.9 \times FREQ. + 1.1 \text{ mA}$ Idle mode:  $I_{CC(MAX)} = 0.18 \times FREQ. + 1.0 \text{ mA}$ ; See Figure 21. 6. This value applies to  $I_{amb} = 0^{\circ}C$  to  $+70^{\circ}C$ . For  $I_{amb} = -40^{\circ}C$  to  $+85^{\circ}C$ ,  $I_{TL} = -750 \mu A$ .
- Load capacitance for port 0, ALE, and PSEN = 100 pF, load capacitance for all other outputs = 80 pF.
- 8. Under steady state (non-transient) conditions,  $I_{OL}$  must be externally limited as follows: Maximum IOL per port pin: 15 mA (\*NOTE: This is 85°C specification.)

Maximum I<sub>OL</sub> per 8-bit port: 26 mA

Maximum total I<sub>OL</sub> for all outputs: 71 mA

If I<sub>OL</sub> exceeds the test condition, V<sub>OL</sub> may exceed the related specification. Pins are not guaranteed to sink current greater than the listed test conditions.

- 9. ALE is tested to  $V_{OH1}$ , except when ALE is off then  $V_{OH}$  is the voltage specification.
- 10. Pin capacitance is characterized but not tested. Pin capacitance is less than 25 pF. Pin capacitance of ceramic package is less than 15 pF
- 11. To improve noise rejection a nominal 100 ns glitch rejection circuitry has been added to the RST pin, and a nominal 15 ns glitch rejection circuitry has been added to the INTO and INTO pins. Previous devices provided only an inherent 5 ns of glitch rejection.

## 80C51/87C51/80C52/87C52

#### **AC ELECTRICAL CHARACTERISTICS**

 $T_{amb} = 0^{\circ}C$  to +70°C or -40°C to +85°C,  $V_{CC} = +2.7$  V to +5.5 V,  $V_{SS} = 0$  V<sup>1, 2, 3</sup>

			16 MHz	CLOCK	VARIABL	E CLOCK	
SYMBOL	FIGURE	PARAMETER	MIN	MAX	MIN	MAX	UNI
1/t <sub>CLCL</sub>	14	Oscillator frequency <sup>5</sup> Speed versions :S			3.5	16	MHz
t <sub>LHLL</sub>	14	ALE pulse width	85		2t <sub>CLCL</sub> -40		ns
t <sub>AVLL</sub>	14	Address valid to ALE low	22		t <sub>CLCL</sub> -40		ns
t <sub>LLAX</sub>	14	Address hold after ALE low	32		t <sub>CLCL</sub> -30		ns
t <sub>LLIV</sub>	14	ALE low to valid instruction in		150		4t <sub>CLCL</sub> -100	ns
t <sub>LLPL</sub>	14	ALE low to PSEN low	32		t <sub>CLCL</sub> -30		ns
t <sub>PLPH</sub>	14	PSEN pulse width	142		3t <sub>CLCL</sub> -45		ns
t <sub>PLIV</sub>	14	PSEN low to valid instruction in		82		3t <sub>CLCL</sub> -105	ns
t <sub>PXIX</sub>	14	Input instruction hold after PSEN	0		0		ns
t <sub>PXIZ</sub>	14	Input instruction float after PSEN		37		t <sub>CLCL</sub> -25	ns
t <sub>AVIV</sub> <sup>4</sup>	14	Address to valid instruction in		207		5t <sub>CLCL</sub> -105	ns
t <sub>PLAZ</sub>	14	PSEN low to address float		10		10	ns
Data Memo	ry			•			
t <sub>RLRH</sub>	15, 16	RD pulse width	275		6t <sub>CLCL</sub> -100		ns
t <sub>WLWH</sub>	15, 16	WR pulse width	275		6t <sub>CLCL</sub> -100		ns
t <sub>RLDV</sub>	15, 16	RD low to valid data in		147		5t <sub>CLCL</sub> -165	ns
t <sub>RHDX</sub>	15, 16	Data hold after RD	0		0		ns
t <sub>RHDZ</sub>	15, 16	Data float after RD		65		2t <sub>CLCL</sub> -60	ns
t <sub>LLDV</sub>	15, 16	ALE low to valid data in		350		8t <sub>CLCL</sub> -150	ns
t <sub>AVDV</sub>	15, 16	Address to valid data in		397		9t <sub>CLCL</sub> -165	ns
t <sub>LLWL</sub>	15, 16	ALE low to RD or WR low	137	239	3t <sub>CLCL</sub> -50	3t <sub>CLCL</sub> +50	ns
t <sub>AVWL</sub>	15, 16	Address valid to WR low or RD low	122		4t <sub>CLCL</sub> -130		ns
t <sub>QVWX</sub>	15, 16	Data valid to WR transition	13		t <sub>CLCL</sub> -50		ns
t <sub>WHQX</sub>	15, 16	Data hold after WR	13		t <sub>CLCL</sub> -50		ns
t <sub>QVWH</sub>	16	Data valid to WR high	287		7t <sub>CLCL</sub> -150		ns
t <sub>RLAZ</sub>	15, 16	RD low to address float		0		0	ns
t <sub>WHLH</sub>	15, 16	RD or WR high to ALE high	23	103	t <sub>CLCL</sub> -40	t <sub>CLCL</sub> +40	ns
External C	lock	•		•	•	•	
t <sub>CHCX</sub>	18	High time	20	Ī	20	t <sub>CLCL</sub> -t <sub>CLCX</sub>	ns
t <sub>CLCX</sub>	18	Low time	20		20	t <sub>CLCL</sub> -t <sub>CHCX</sub>	ns
tclch	18	Rise time		20		20	ns
t <sub>CHCL</sub>	18	Fall time	1	20		20	ns
Shift Regis	ter		•		•		
t <sub>XLXL</sub>	17	Serial port clock cycle time	750		12t <sub>CLCL</sub>		ns
t <sub>QVXH</sub>	17	Output data setup to clock rising edge	492		10t <sub>CLCL</sub> -133		ns
t <sub>XHQX</sub>	17	Output data hold after clock rising edge	8		2t <sub>CLCL</sub> -117		ns
t <sub>XHDX</sub>	17	Input data hold after clock rising edge	0	1	0		ns
t <sub>XHDV</sub>	17	Clock rising edge to input data valid	$\overline{}$	492		10t <sub>CLCL</sub> -133	ns

- Parameters are valid over operating temperature range unless otherwise specified.
   Load capacitance for port 0, ALE, and PSEN = 100 pF, load capacitance for all other outputs = 80 pF.
- 3. Interfacing the 87C51, 80C51, 87C52, or 80C52 to devices with float times up to 45 ns is permitted. This limited bus contention will not cause damage to Port 0 drivers.
- 4. See application note AN457 for external memory interface.
- 5. Parts are guaranteed to operate down to 0 Hz. When an external clock source is used, the RST pin should be held high for a minimum of 20 µs for power-on or wakeup from power down.

## 80C51/87C51/80C52/87C52

#### **AC ELECTRICAL CHARACTERISTICS**

 $T_{amb} = 0^{\circ}C$  to +70°C or -40°C to +85°C,  $V_{CC} = 5 \text{ V} \pm 10\%$ ,  $V_{SS} = 0 \text{ V}^{1, 2, 3}$ 

				E CLOCK <sup>4</sup> z to f <sub>max</sub>	33 MH2	CLOCK	
SYMBOL	FIGURE	PARAMETER	MIN	MAX	MIN	MAX	H UNIT
tLHLL	14	ALE pulse width	2t <sub>CLCL</sub> -40		21		ns
t <sub>AVLL</sub>	14	Address valid to ALE low	t <sub>CLCL</sub> -25		5		ns
t <sub>LLAX</sub>	14	Address hold after ALE low	t <sub>CLCL</sub> -25		Ť		ns
t <sub>LLIV</sub>	14	ALE low to valid instruction in	TOLOL 20	4t <sub>CLCL</sub> -65		55	ns
t <sub>LLPL</sub>	14	ALE low to PSEN low	t <sub>CLCL</sub> -25	GLGL 11	5		ns
t <sub>PLPH</sub>	14	PSEN pulse width	3t <sub>CLCL</sub> -45		45		ns
t <sub>PLIV</sub>	14	PSEN low to valid instruction in	0202	3t <sub>CLCL</sub> -60		30	ns
t <sub>PXIX</sub>	14	Input instruction hold after PSEN	0	0202	0		ns
t <sub>PXIZ</sub>	14	Input instruction float after PSEN		t <sub>CLCL</sub> -25		5	ns
t <sub>AVIV</sub>	14	Address to valid instruction in		5t <sub>CLCL</sub> -80		70	ns
t <sub>PLAZ</sub>	14	PSEN low to address float		10		10	ns
Data Memor	ry	•	•				
t <sub>RLRH</sub>	15, 16	RD pulse width	6t <sub>CLCL</sub> -100		82		ns
t <sub>WLWH</sub>	15, 16	WR pulse width	6t <sub>CLCL</sub> -100		82		ns
t <sub>RLDV</sub>	15, 16	RD low to valid data in		5t <sub>CLCL</sub> -90		60	ns
t <sub>RHDX</sub>	15, 16	Data hold after RD	0		0		ns
t <sub>RHDZ</sub>	15, 16	Data float after RD		2t <sub>CLCL</sub> -28		32	ns
t <sub>LLDV</sub>	15, 16	ALE low to valid data in		8t <sub>CLCL</sub> -150		90	ns
t <sub>AVDV</sub>	15, 16	Address to valid data in		9t <sub>CLCL</sub> -165		105	ns
t <sub>LLWL</sub>	15, 16	ALE low to RD or WR low	3t <sub>CLCL</sub> -50	3t <sub>CLCL</sub> +50	40	140	ns
t <sub>AVWL</sub>	15, 16	Address valid to WR low or RD low	4t <sub>CLCL</sub> -75		45		ns
t <sub>QVWX</sub>	15, 16	Data valid to WR transition	t <sub>CLCL</sub> -30		0		ns
t <sub>WHQX</sub>	15, 16	Data hold after WR	t <sub>CLCL</sub> -25		5		ns
t <sub>QVWH</sub>	16	Data valid to WR high	7t <sub>CLCL</sub> -130		80		ns
t <sub>RLAZ</sub>	15, 16	RD low to address float		0		0	ns
t <sub>WHLH</sub>	15, 16	RD or WR high to ALE high	t <sub>CLCL</sub> -25	t <sub>CLCL</sub> +25	5	55	ns
External Clo	ock						
t <sub>CHCX</sub>	18	High time	0.38t <sub>CLCL</sub>	t <sub>CLCL</sub> -t <sub>CLCX</sub>			ns
t <sub>CLCX</sub>	18	Low time	0.38t <sub>CLCL</sub>	t <sub>CLCL</sub> -t <sub>CHCX</sub>			ns
t <sub>CLCH</sub>	18	Rise time		5			ns
t <sub>CHCL</sub>	18	Fall time		5			ns
Shift Regist	er				_		
t <sub>XLXL</sub>	17	Serial port clock cycle time	12t <sub>CLCL</sub>		360		ns
t <sub>QVXH</sub>	17	Output data setup to clock rising edge	10t <sub>CLCL</sub> -133		167		ns
t <sub>XHQX</sub>	17	Output data hold after clock rising edge	2t <sub>CLCL</sub> -80				ns
t <sub>XHDX</sub>	17	Input data hold after clock rising edge	0		0		ns
t <sub>XHDV</sub>	17	Clock rising edge to input data valid		10t <sub>CLCL</sub> -133		167	ns

#### NOTES:

- 1. Parameters are valid over operating temperature range unless otherwise specified.
- 2. Load capacitance for port 0, ALE, and  $\overline{PSEN} = 100 \, pF$ , load capacitance for all other outputs = 80 pF.
- 3. Interfacing the 87C51, 80C51, 87C52 or 80C52 to devices with float times up to 45ns is permitted. This limited bus contention will not cause damage to Port 0 drivers.
- 4. Variable clock is specified for oscillator frequencies greater than 16 MHz to 33 MHz. For frequencies equal or less than 16 MHz, see 16 MHz "AC Electrical Characteristics", page 24.
- 5. Parts are guaranteed to operate down to 0 Hz. When an external clock source is used, the RST pin should be held high for a minimum of 20 μs for power-on or wakeup from power down.

## 80C51/87C51/80C52/87C52

#### **EXPLANATION OF THE AC SYMBOLS**

Each timing symbol has five characters. The first character is always 't' (= time). The other characters, depending on their positions, indicate the name of a signal or the logical status of that signal. The designations are:

A - Address

C - Clock

D - Input data

H - Logic level high

I – Instruction (program memory contents)

L - Logic level low, or ALE

P - PSEN

Q - Output data

R - RD signal

t - Time

V - Valid

W- WR signal

X - No longer a valid logic level

Z - Float

**Examples:**  $t_{AVLL}$  = Time for address valid to ALE low.

 $t_{LLPL}$  =Time for ALE low to  $\overline{PSEN}$  low.

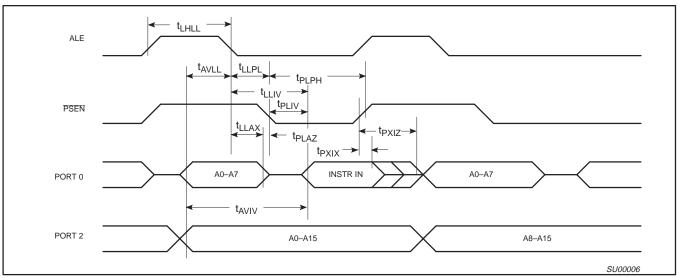


Figure 14. External Program Memory Read Cycle

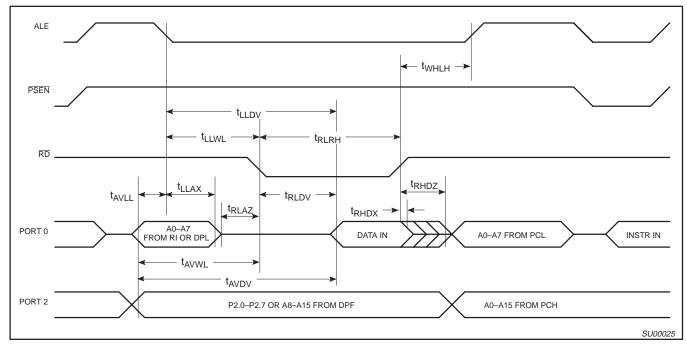


Figure 15. External Data Memory Read Cycle

## 80C51/87C51/80C52/87C52

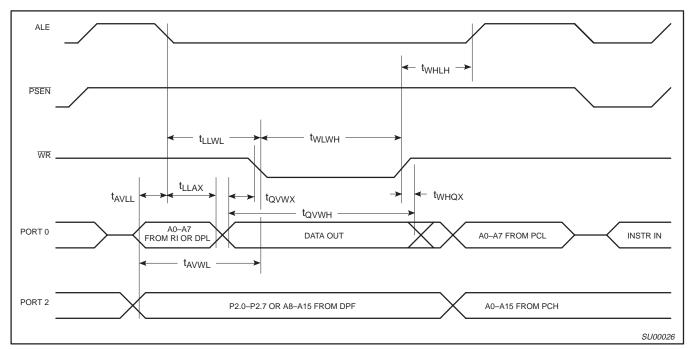


Figure 16. External Data Memory Write Cycle

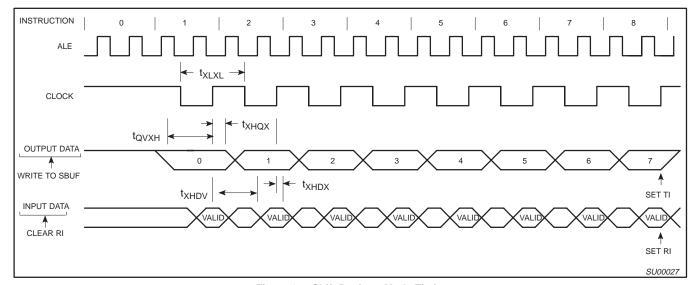


Figure 17. Shift Register Mode Timing

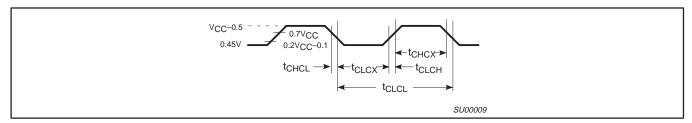


Figure 18. External Clock Drive

Philips Semiconductors Product specification

80C51 8-bit microcontroller family 4 K/8 K OTP/ROM low voltage (2.7 V-5.5 V), low power, high speed (33 MHz), 128/256 B RAM

## 80C51/87C51/80C52/87C52

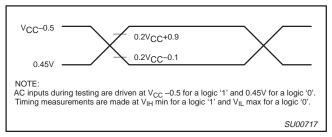


Figure 19. AC Testing Input/Output

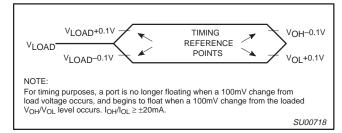
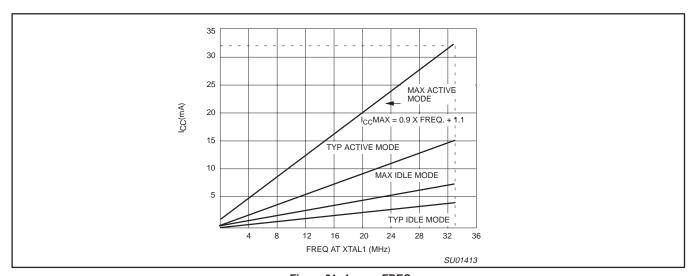


Figure 20. Float Waveform



 $\label{eq:continuous} \mbox{Figure 21. I}_{\mbox{CC}} \mbox{ vs. FREQ} \\ \mbox{Valid only within frequency specifications of the device under test}$ 

## 80C51/87C51/80C52/87C52

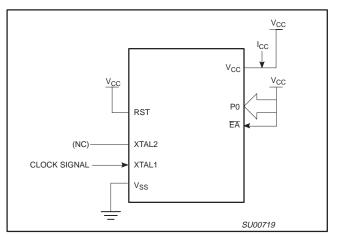


Figure 22. I<sub>CC</sub> Test Condition, Active Mode All other pins are disconnected

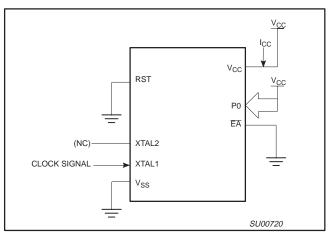


Figure 23. I<sub>CC</sub> Test Condition, Idle Mode All other pins are disconnected

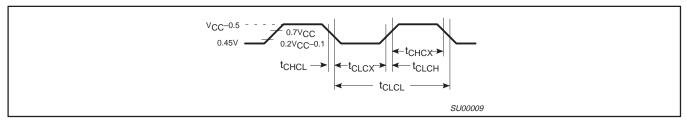


Figure 24. Clock Signal Waveform for  $I_{CC}$  Tests in Active and Idle Modes  $t_{CLCH}$  =  $t_{CHCL}$  = 5ns

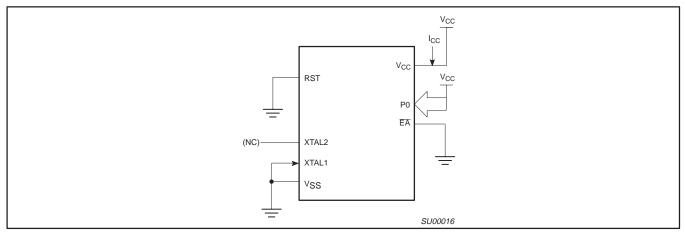


Figure 25.  $I_{CC}$  Test Condition, Power Down Mode All other pins are disconnected.  $V_{CC}$  = 2 V to 5.5 V

## 80C51/87C51/80C52/87C52

#### **EPROM CHARACTERISTICS**

These devices can be programmed by using a modified Improved Quick-Pulse Programming<sup>™</sup> algorithm. It differs from older methods in the value used for  $V_{PP}$  (programming supply voltage) and in the width and number of the ALE/PROG pulses.

The family contains two signature bytes that can be read and used by an EPROM programming system to identify the device. The signature bytes identify the device as being manufactured by Philips.

Table 8 shows the logic levels for reading the signature byte, and for programming the program memory, the encryption table, and the security bits. The circuit configuration and waveforms for quick-pulse programming are shown in Figures 26 and 27. Figure 28 shows the circuit configuration for normal program memory verification.

#### **Quick-Pulse Programming**

The setup for microcontroller quick-pulse programming is shown in Figure 26. Note that the device is running with a 4 to 6 MHz oscillator. The reason the oscillator needs to be running is that the device is executing internal address and program data transfers.

The address of the EPROM location to be programmed is applied to ports 1 and 2, as shown in Figure 26. The code byte to be programmed into that location is applied to port 0. RST, PSEN and pins of ports 2 and 3 specified in Table 8 are held at the 'Program Code Data' levels indicated in Table 8. The ALE/PROG is pulsed low 5 times as shown in Figure 27.

To program the encryption table, repeat the 5 pulse programming sequence for addresses 0 through 1FH, using the 'Pgm Encryption Table' levels. Do not forget that after the encryption table is programmed, verification cycles will produce only encrypted data.

To program the security bits, repeat the 5 pulse programming sequence using the 'Pgm Security Bit' levels. After one security bit is programmed, further programming of the code memory and encryption table is disabled. However, the other security bits can still be programmed.

Note that the  $\overline{\text{EA}/\text{V}_{PP}}$  pin must not be allowed to go above the maximum specified  $\text{V}_{PP}$  level for any amount of time. Even a narrow glitch above that voltage can cause permanent damage to the

device. The  $\ensuremath{\text{V}_{\text{PP}}}$  source should be well regulated and free of glitches and overshoot.

#### **Program Verification**

If security bits 2 and 3 have not been programmed, the on-chip program memory can be read out for program verification. The address of the program memory locations to be read is applied to ports 1 and 2 as shown in Figure 28. The other pins are held at the 'Verify Code Data' levels indicated in Table 8. The contents of the address location will be emitted on port 0. External pull-ups are required on port 0 for this operation.

If the 64 byte encryption table has been programmed, the data presented at port 0 will be the exclusive NOR of the program byte with one of the encryption bytes. The user will have to know the encryption table contents in order to correctly decode the verification data. The encryption table itself cannot be read out.

#### Reading the Signature Bytes

The signature bytes are read by the same procedure as a normal verification of locations 030H and 031H, except that P3.6 and P3.7 need to be pulled to a logic low. The values are:

(030H) = 15H indicates manufactured by Philips

(031H) = 92H indicates 87C51

#### **Program/Verify Algorithms**

Any algorithm in agreement with the conditions listed in Table 8, and which satisfies the timing specifications, is suitable.

#### **Security Bits**

With none of the security bits programmed the code in the program memory can be verified. If the encryption table is programmed, the code will be encrypted when verified. When only security bit 1 (see Table 9) is programmed, MOVC instructions executed from external program memory are disabled from fetching code bytes from the internal memory, EA is latched on Reset and all further programming of the EPROM is disabled. When security bits 1 and 2 are programmed, in addition to the above, verify mode is disabled. When all three security bits are programmed, all of the conditions above apply and all external program memory execution is disabled.

#### **Encryption Array**

64 bytes of encryption array are initially unprogrammed (all 1s).

**Table 8. EPROM Programming Modes** 

iable of El Rolli Frogran	ng mode	•						
MODE	RST	PSEN	ALE/PROG	EA/V <sub>PP</sub>	P2.7	P2.6	P3.7	P3.6
Read signature	1	0	1	1	0	0	0	0
Program code data	1	0	0*	V <sub>PP</sub>	1	0	1	1
Verify code data	1	0	1	1	0	0	1	1
Pgm encryption table	1	0	0*	V <sub>PP</sub>	1	0	1	0
Pgm security bit 1	1	0	0*	$V_{PP}$	1	1	1	1
Pgm security bit 2	1	0	0*	$V_{PP}$	1	1	0	0
Pgm security bit 3	1	0	0*	$V_{PP}$	0	1	0	1

#### NOTES:

- 1. '0' = Valid low for that pin, '1' = valid high for that pin.
- 2.  $V_{PP} = 12.75 \text{ V} \pm 0.25 \text{ V}.$
- 3.  $V_{CC} = 5 \text{ V} \pm 10\%$  during programming and verification.
- ALE/PROG receives 5 programming pulses for code data (also for user array; 5 pulses for encryption or security bits) while V<sub>PP</sub> is held at 12.75 V. Each programming pulse is low for 100 μs (±10 μs) and high for a minimum of 10 μs.

<sup>™</sup>Trademark phrase of Intel Corporation.

Table 9. Program Security Bits for EPROM Devices

PRO	OGRAM L	оск вітя	31, 2	
	SB1	SB2	SB3	PROTECTION DESCRIPTION
1	U	U	U	No Program Security features enabled. (Code verify will still be encrypted by the Encryption Array if programmed.)
2	Р	U	U	MOVC instructions executed from external program memory are disabled from fetching code bytes from internal memory, $\overline{EA}$ is sampled and latched on Reset, and further programming of the EPROM is disabled.
3	Р	Р	U	Same as 2, also verify is disabled.
4	Р	Р	Р	Same as 3, external execution is disabled. Internal data RAM is not accessible.

#### NOTES:

- P programmed. U unprogrammed.
   Any other combination of the security bits is not defined.

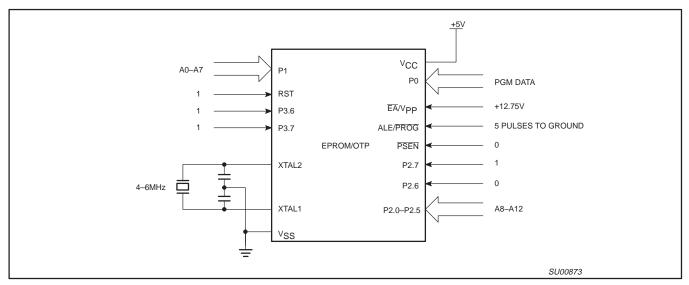


Figure 26. Programming Configuration

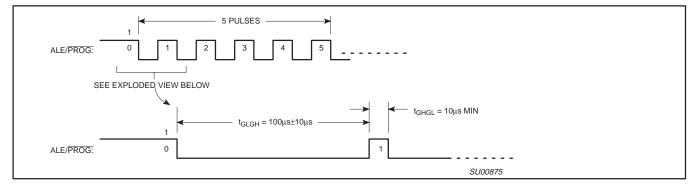


Figure 27. PROG Waveform

## 80C51/87C51/80C52/87C52

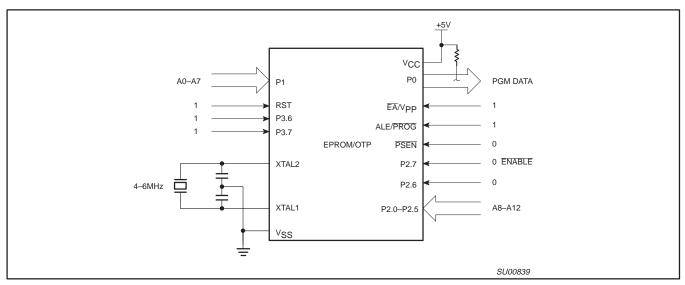


Figure 28. Program Verification

#### **EPROM PROGRAMMING AND VERIFICATION CHARACTERISTICS**

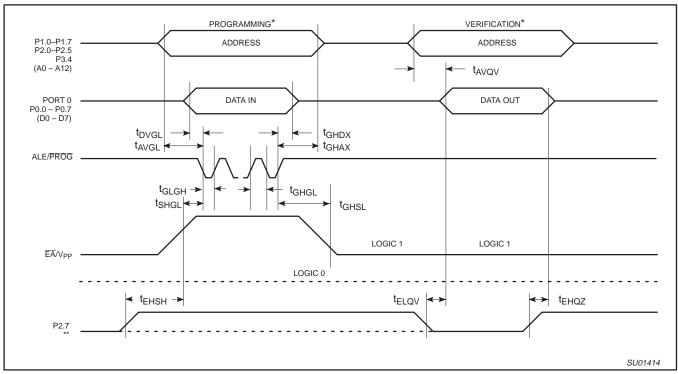
 $T_{amb} = 21^{\circ}C$  to +27°C,  $V_{CC} = 5$  V±10%,  $V_{SS} = 0$  V (See Figure 29)

SYMBOL	PARAMETER	MIN	MAX	UNIT
V <sub>PP</sub>	Programming supply voltage	12.5	13.0	V
I <sub>PP</sub>	Programming supply current		50 <sup>1</sup>	mA
1/t <sub>CLCL</sub>	Oscillator frequency	4	6	MHz
t <sub>AVGL</sub>	Address setup to PROG low	48t <sub>CLCL</sub>		
t <sub>GHAX</sub>	Address hold after PROG	48t <sub>CLCL</sub>		
t <sub>DVGL</sub>	Data setup to PROG low	48t <sub>CLCL</sub>		
t <sub>GHDX</sub>	Data hold after PROG	48t <sub>CLCL</sub>		
t <sub>EHSH</sub>	P2.7 (ENABLE) high to V <sub>PP</sub>	48t <sub>CLCL</sub>		
t <sub>SHGL</sub>	V <sub>PP</sub> setup to PROG low	10		μs
t <sub>GHSL</sub>	V <sub>PP</sub> hold after PROG	10		μs
t <sub>GLGH</sub>	PROG width	90	110	μs
t <sub>AVQV</sub>	Address to data valid		48t <sub>CLCL</sub>	
t <sub>ELQZ</sub>	ENABLE low to data valid		48t <sub>CLCL</sub>	
t <sub>EHQZ</sub>	Data float after ENABLE	0	48t <sub>CLCL</sub>	
t <sub>GHGL</sub>	PROG high to PROG low	10		μs

#### NOTE:

1. Not tested.

## 80C51/87C51/80C52/87C52



#### NOTES:

- \* FOR PROGRAMMING CONFIGURATION SEE FIGURE 26 FOR VERIFICATION CONDITIONS SEE FIGURE 28.
- \*\* SEE TABLE 8.

Figure 29. EPROM Programming and Verification

#### MASK ROM DEVICES

### **Security Bits**

With none of the security bits programmed the code in the program memory can be verified. If the encryption table is programmed, the code will be encrypted when verified. When only security bit 1 (see Table 10) is programmed, MOVC instructions executed from external program memory are disabled from fetching code bytes

from the internal memory,  $\overline{EA}$  is latched on Reset and all further programming of the EPROM is disabled. When security bits 1 and 2 are programmed, in addition to the above, verify mode is disabled.

#### **Encryption Array**

64 bytes of encryption array are initially unprogrammed (all 1s).

**Table 10. Program Security Bits** 

PROGR	AM LOCK	BITS <sup>1, 2</sup>								
	SB1	SB2	PROTECTION DESCRIPTION							
1	U	U	No Program Security features enabled. (Code verify will still be encrypted by the Encryption Array if programmed.)							
2	Р		MOVC instructions executed from external program memory are disabled from fetching code bytes from internal memory, $\overline{EA}$ is sampled and latched on Reset, and further programming of the EPROM is disabled.							

#### NOTES:

- 1. P programmed. U unprogrammed.
- 2. Any other combination of the security bits is not defined.

Philips Semiconductors Product specification

80C51 8-bit microcontroller family 4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V), low power, high speed (33 MHz), 128/256 B RAM

## 80C51/87C51/80C52/87C52

#### 80C51 ROM CODE SUBMISSION

When submitting ROM code for the 80C51, the following must be specified:

- 1. 4k byte user ROM data
- 2. 64 byte ROM encryption key
- 3. ROM security bits.

ADDRESS	CONTENT	BIT(S)	COMMENT
0000H to 0FFFH	DATA	7:0	User ROM Data
1000H to 103FH	KEY	7:0	ROM Encryption Key
1040H	SEC	0	ROM Security Bit 1
1040H	SEC	1	ROM Security Bit 2

Security Bit 1: When programmed, this bit has two effects on masked ROM parts:

- 1. External MOVC is disabled, and
- 2. EA is latched on Reset.

Security Bit 2: When programmed, this bit inhibits Verify User ROM.

NOTE: Security Bit 2 cannot be enabled unless Security Bit 1 is enabled.

If the ROM Code file does not include the options, the following information must be included with the ROM code.

For each of the following, check the appropriate box, and send to Philips along with the code:

Security Bit #1:	□ Enabled	☐ Disable	ed
Security Bit #2:	☐ Enabled	☐ Disable	ed
Encryption:	□ No	□ Yes	If Yes, must send key file.

#### 80C52 ROM CODE SUBMISSION

When submitting ROM code for the 80C52, the following must be specified:

- 1. 8k byte user ROM data
- 2. 64 byte ROM encryption key
- 3. ROM security bits.

ADDRESS	CONTENT	BIT(S)	COMMENT
0000H to 1FFFH	DATA	7:0	User ROM Data
2000H to 203FH	KEY	7:0	ROM Encryption Key
2040H	SEC	0	ROM Security Bit 1
2040H	SEC	1	ROM Security Bit 2

Security Bit 1: When programmed, this bit has two effects on masked ROM parts:

- 1. External MOVC is disabled, and
- 2. EA is latched on Reset.

Security Bit 2: When programmed, this bit inhibits Verify User ROM.

NOTE: Security Bit 2 cannot be enabled unless Security Bit 1 is enabled.

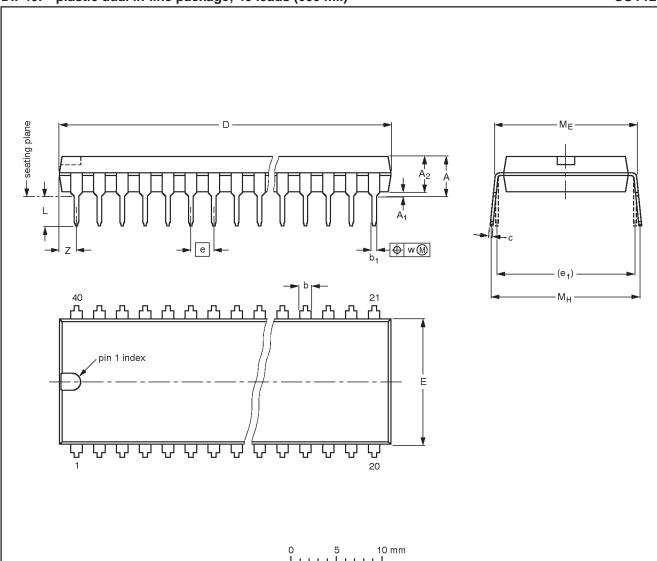
If the ROM Code file does not include the options, the following information must be included with the ROM code.

For each of the following, check the appropriate box, and send to Philips along with the code:

Security Bit #1:	☐ Enabled	☐ Disabled
Security Bit #2:	☐ Enabled	☐ Disabled
Encryption:	□ No	☐ Yes If Yes, must send key file

## DIP40: plastic dual in-line package; 40 leads (600 mil)

SOT129-1



## Scale

#### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	Мн	w	Z <sup>(1)</sup> max.
mm	4.7	0.51	4.0	1.70 1.14	0.53 0.38	0.36 0.23	52.50 51.50	14.1 13.7	2.54	15.24	3.60 3.05	15.80 15.24	17.42 15.90	0.254	2.25
inches	0.19	0.020	0.16	0.067 0.045	0.021 0.015	0.014 0.009	2.067 2.028	0.56 0.54	0.10	0.60	0.14 0.12	0.62 0.60	0.69 0.63	0.01	0.089

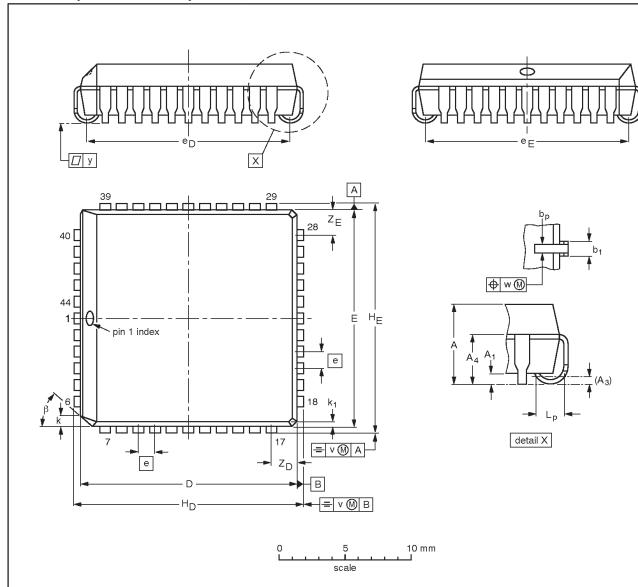
#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE		
SOT129-1	051G08	MO-015	SC-511-40		<del>95-01-14</del> 99-12-27		

## PLCC44: plastic leaded chip carrier; 44 leads

SOT187-2



### DIMENSIONS (millimetre dimensions are derived from the original inch dimensions)

UNIT	Α	A <sub>1</sub> min.	A <sub>3</sub>	A <sub>4</sub> max.	bp	b <sub>1</sub>	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>D</sub>	еE	H <sub>D</sub>	HE	k	k <sub>1</sub> max.	Lp	v	w	у		- 1	β
mm	4.57 4.19	0.51	0.25	3.05	0.53 0.33			16.66 16.51		16.00 14.99					0.51	1.44 1.02	0.18	0.18	0.10	2.16	2.16	45°
inches	0.180 0.165	0.020	0.01			0.032 0.026			0.05	0.630 0.590	0.630 0.590	0.695 0.685	0.695 0.685	0.048 0.042	0.020	0.057 0.040	0.007	0.007	0.004	0.085	0.085	40

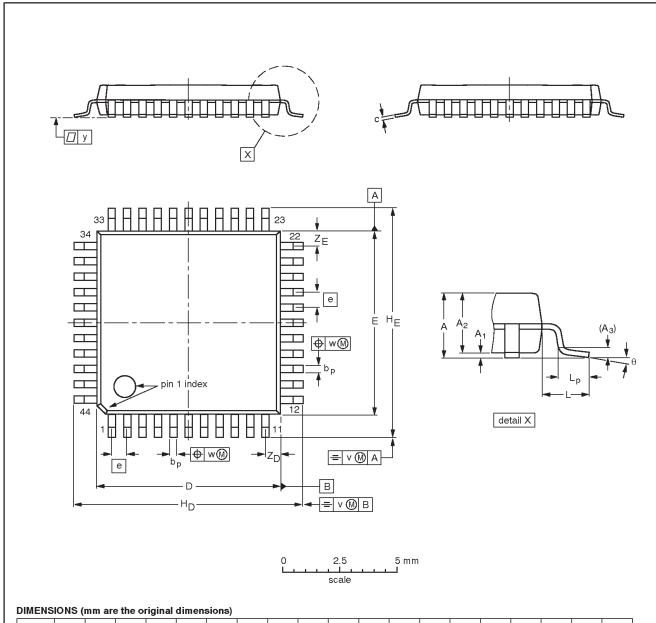
#### Note

1. Plastic or metal protrusions of 0.01 inches maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1330E DATE
SOT187-2	112E10	MO-047				<del>97-12-16</del> 99-12-27

## QFP44: plastic quad flat package; 44 leads (lead length 1.3 mm); body 10 x 10 x 1.75 mm

SOT307-2



UNIT	A max.	Α1	A <sub>2</sub>	A <sub>3</sub>	Ьp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	H <sub>D</sub>	HE	L	Lp	v	w	у	Z <sub>D</sub> <sup>(1)</sup>	Z <sub>E</sub> <sup>(1)</sup>	θ
mm	2.10	0.25 0.05	1.85 1.65	0.25	0.40 0.20	0.25 0.14	10.1 9.9	10.1 9.9	0.8	12.9 12.3	12.9 12.3	1.3	0.95 0.55	0.15	0.15	0.1	1.2 0.8	1.2 0.8	10° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT307-2						<del>-95-02-04</del> 97-08-01

## 80C51/87C51/80C52/87C52

#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

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Date of release: 08-00

Document order number: 9397 750 07404

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